

# Si5330x Data Sheet

# Ultra-Low Additive Jitter Fanout Clock Buffers with up to 10 Universal Outputs from Any-Format Input and Wide Frequency Range from 1 MHz to 725 MHz

The Si5330x family of Universal/Any-format fanout buffers is ideal for clock distribution (1 MHz minimum) and redundant clocking applications. These devices feature typical ultra-low jitter characteristics of 50 fs and operate over a wide frequency range. Built-in LDOs deliver high PSRR performance and reduce the need for external components, simplifying low-jitter clock distribution in noisy environments.

The Si5330x family is available in multiple configurations, with some versions offering a selectable input clock using a 2:1 input mux. Other features include independent (synchronous) output enable, glitchless switching, LOS monitor of input clocks, output clock division, and built-in format translation. These buffers can be paired with the Si534x clocks and jitter attenuators, the Si5332 clocks, and the Si5xx oscillators to deliver end-to-end clock tree performance.

#### **KEY FEATURES**

- · Ultra-low additive jitter: 50 fs rms
- · Built-in LDOs for high PSRR performance
- Up to 10 outputs
- Any-format Inputs (LVPECL, Low-power LVPECL, LVDS, CML, HCSL, LVCMOS)
- · Wide frequency range
- · Output Enable option
- · Multiple configuration options
  - Dual Bank option
  - 2:1 Input Mux operation
- · Synchronous output enable
- Loss of signal (LOS) monitors for loss of input clock
- Output clock division: /1, /2, /4
- · RoHS compliant, Pb-free
- Temperature range: -40 to +85 °C

# 1. Ordering Guide

**Table 1.1. Product Family Overview** 

| Part<br>Number | Description                                   | Input<br>MUX | Input | Output             | Glitch-<br>less<br>Switch <sup>1</sup> | LOS<br>Output | OE<br>Option | Synchro-<br>nous OE <sup>1</sup> | Clk Divid-<br>er Option |
|----------------|---|--------------|-------|--------------------|--|---------------|--------------|----------------------------------|-------------------------|
| Si53301-B-GM   | 6 output universal buffer with 2:1 input mux  | Yes          | 2     | 6 Diff / 12<br>SE  | Yes                                    | Yes           | Per Bank     | Yes                              | Per Bank                |
| Si53302-B-GM   | 10 output universal buffer with 2:1 input mux | Yes          | 2     | 10 Diff / 20<br>SE | Yes                                    | Yes           | Per Bank     | Yes                              | Per Bank                |
| Si53303-B-GM   | Dual 1:5 universal buffer                     | No           | 2     | 5 Diff / 10<br>SE  | No                                     | No            | Per Bank     | Yes                              | Per Bank                |
| Si53304-B-GM   | 6 output universal buffer with 2:1 input mux  | Yes          | 2     | 6 Diff / 12<br>SE  | Yes                                    | No            | Individual   | Yes                              | No                      |
| Si53305-B-GM   | 10 output universal buffer with 2:1 input mux | Yes          | 2     | 10 Diff / 20<br>SE | Yes                                    | No            | Individual   | Yes                              | No                      |
| Si53306-B-GM   | 4 output universal buffer, single input       | No           | 1     | 4 Diff / 8 SE      | No                                     | No            | Single       | Yes                              | No                      |
| Si53307-B-GM   | 2 output universal buffer with 2:1 input mux  | Yes          | 2     | 2 Diff / 4 SE      | Yes                                    | No            | Single       | Yes                              | No                      |
| Si53308-B-GM   | Dual 1:3 universal buffer                     | No           | 2     | 3 Diff / 6 SE      | No                                     | Yes           | Per Bank     | Yes                              | Per Bank                |

# Note:

- 1. The synchronous features (Glitch-less switching and Synchronous OE) of the Si533xx family require a minimum input clock frequency of 1 MHz. If the selected input clock stops, pauses, or is gapped such that the 1 MHz minimum is not met for any time interval, then the output clock(s) will be disabled (turned off). Once the paused input clock restarts, the output clock may NOT start up immediately. Output start-up (turning back on) may be delayed for several input clock cycles until the internal synchronizer determines the input clock is once again valid.
- 2. Click on the part number above to see a block diagram for each corresponding part number.

Table 1.2. Si5330x Ordering Guide

| Part Number               | Package          | Pb-Free, ROHS-6 | Temperature  |
|---------------------------|------------------|-----------------|--------------|
| Si53301-B-GM <sup>1</sup> | 32-QFN           | Yes             | –40 to 85 °C |
| Si53302-B-GM <sup>1</sup> | 44-QFN           | Yes             | –40 to 85 °C |
| Si53303-B-GM <sup>1</sup> | 44-QFN           | Yes             | –40 to 85 °C |
| Si53304-B-GM <sup>1</sup> | 32-QFN           | Yes             | –40 to 85 °C |
| Si53305-B-GM <sup>1</sup> | 44-QFN           | Yes             | –40 to 85 °C |
| Si53306-B-GM <sup>1</sup> | 16-QFN           | Yes             | –40 to 85 °C |
| Si53307-B-GM <sup>1</sup> | 16-QFN           | Yes             | –40 to 85 °C |
| Si53308-B-GM <sup>1</sup> | 32-QFN           | Yes             | –40 to 85 °C |
| Si53301/4-EVB             | Evaluation Board | _               | _            |

#### Note:

1. Add an "R" at the end of the OPN to denote tape and reel ordering options.

# **Table of Contents**

| 1. | Ordering Guide  |     | . 2  |
|----|---|-----|------|
| 2. | Functional Description  |     | . 5  |
|    | 2.1 Universal, Any-Format Input Termination                     |     | . 5  |
|    | 2.2 Internal Input Bias Resistors                               |     | . 8  |
|    | 2.3 Voltage Reference (V <sub>REF</sub> )                       |     | . 9  |
|    | 2.4 Universal, Any-Format Output Buffer                         |     | . 9  |
|    | 2.5 Input Mux (Si53301/02/04/05/07 Only)                        |     | .10  |
|    | 2.6 Glitchless Clock Input Switching                            |     | .10  |
|    | 2.7 Synchronous Output Enable                                   |     | .10  |
|    | 2.8 Loss of Signal (LOS) Indicator                              |     | . 11 |
|    | 2.9 Flexible Output Divider                                     |     | . 11 |
|    | 2.10 Power Supply (V <sub>DD</sub> and V <sub>DDOX</sub> )      |     | . 11 |
|    | 2.11 Output Clock Termination Options                           |     | .12  |
|    | 2.12 LVCMOS Output Termination to Support 1.5 V and 1.2 V       |     | .14  |
|    | 2.13 AC Timing Waveforms  |     | .15  |
|    | 2.14 Typical Phase Noise Performance (Differential Input Clock) |     | .16  |
|    | 2.15 Typical Phase Noise Performance (Single-Ended Input Clock) |     | .18  |
|    | 2.16 Input Mux Noise Isolation                                  |     | .19  |
|    | 2.17 Power Supply Noise Rejection                               |     | .19  |
| 3. | Electrical Specifications                                       |     | 20   |
| 4. | Detailed Block Diagrams   |     | 29   |
| 5. | Pin Descriptions  |     | 36   |
|    | 5.1 Si53301 Pin Descriptions                                    |     |      |
|    | 5.2 Si53302 Pin Descriptions                                    | . , | .39  |
|    | 5.3 Si53303 Pin Descriptions                                    |     |      |
|    | 5.4 Si53304 Pin Descriptions                                    |     | .45  |
|    | 5.5 Si53305 Pin Descriptions                                    |     | .48  |
|    | 5.6 Si53306 Pin Descriptions                                    |     | .52  |
|    | 5.7 Si53307 Pin Descriptions                                    |     | .54  |
|    | 5.8 Si53308 Pin Descriptions                                    |     | .56  |
| 6. | Package Outlines  | 1   | 59   |
|    | 6.1 16-QFN Package Diagram                                      | . , | .59  |
|    | 6.2 32-QFN Package Diagram                                      |     | .60  |
|    | 6.3 44-QFN Package Diagram                                      |     |      |
| 7. | Land Patterns   | 1   | 62   |
|    |   |     |      |

| 9. | Revision History               |  |  |  |  |  |  |  |  |  |  |  |  | 68  |
|----|--------------------------------|--|--|--|--|--|--|--|--|--|--|--|--|-----|
|    | 8.3 Si53306/07 Top Markings .  |  |  |  |  |  |  |  |  |  |  |  |  | .67 |
|    | 8.2 Si53302/03/05 Top Markings |  |  |  |  |  |  |  |  |  |  |  |  | .66 |
|    | 8.1 Si53301/04/08 Top Markings |  |  |  |  |  |  |  |  |  |  |  |  | .65 |
| 8. | Top Markings                   |  |  |  |  |  |  |  |  |  |  |  |  | 65  |
|    | 7.3 44-QFN Land Pattern        |  |  |  |  |  |  |  |  |  |  |  |  | .64 |
|    | 7.2 32-QFN Land Pattern        |  |  |  |  |  |  |  |  |  |  |  |  | .63 |
|    | 7.1 16-QFN Land Pattern        |  |  |  |  |  |  |  |  |  |  |  |  | .62 |

# 2. Functional Description

The Si5330x family of low-jitter, low-skew, universal/any-format buffers accepts most common differential or LVCMOS input signals. These devices are available in multiple configurations customized for the end application (refer to 1. Ordering Guide for more details on configurations).

#### 2.1 Universal, Any-Format Input Termination

The universal input stage enables simple interfacing to a wide variety of clock formats, including LVPECL, low-power LVPECL, LVCMOS, LVDS, HCSL, and CML. The simplified tables below summarize the various ac- and dc-coupling options supported by the device. For the best high-speed performance, the use of differential formats is recommended. For both single-ended and differential input clocks, the fastest possible slew rate is recommended since low slew rates can increase the noise floor and degrade jitter performance. Though not required, a minimum slew rate of 0.75 V/ns is recommended for differential formats and 1.0 V/ns for single-ended formats. See AN766: Understanding and Optimizing Clock Buffer's Additive Jitter Performance for more information.

**Table 2.1. AC-Coupled Clock Input Options** 

| Clock Format            | 1.8 V | 2.5/3.3 V |
|-------------------------|-------|-----------|
| LVPECL/Low-power LVPECL | N/A   | Yes       |
| LVCMOS                  | No    | Yes       |
| LVDS                    | Yes   | Yes       |
| HCSL                    | No    | Yes       |
| CML                     | Yes   | Yes       |

Table 2.2. DC-Coupled Clock Input Options

| Clock Format            | 1.8 V | 2.5/3.3 V |
|-------------------------|-------|-----------|
| LVPECL/Low-power LVPECL | N/A   | Yes       |
| LVCMOS                  | No    | Yes       |
| LVDS                    | No    | Yes       |
| HCSL                    | No    | Yes       |
| CML                     | No    | No        |

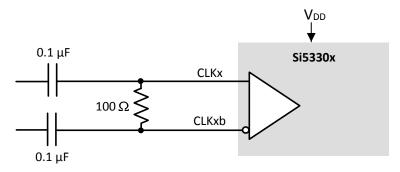


Figure 2.1. Differential (HCSL, LVPECL, Low-Power LVPECL, LVDS, CML) AC-Coupled Input Termination

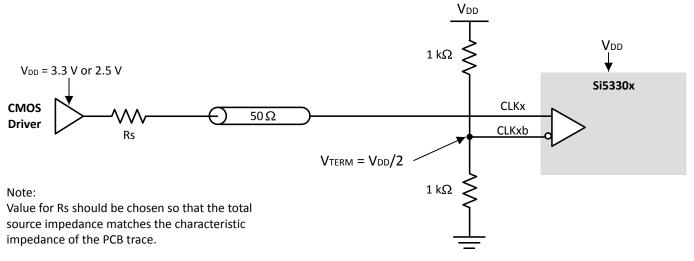


Figure 2.2. DC-Coupled, Single-Ended (LVCMOS) Input Termination

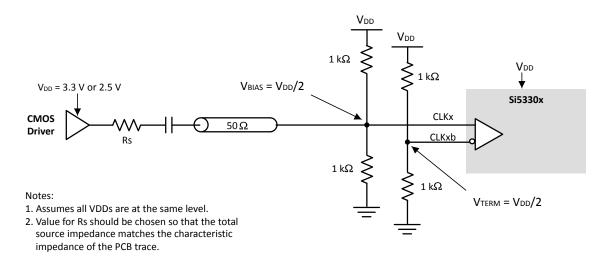
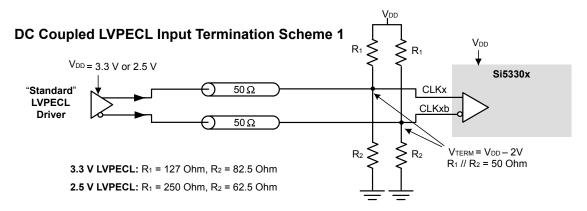
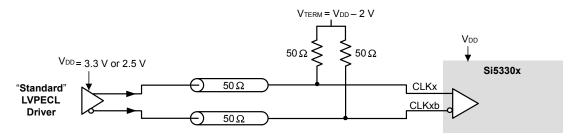
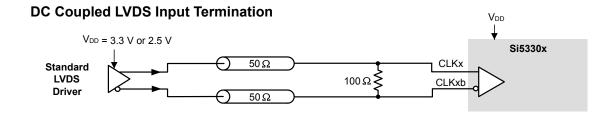


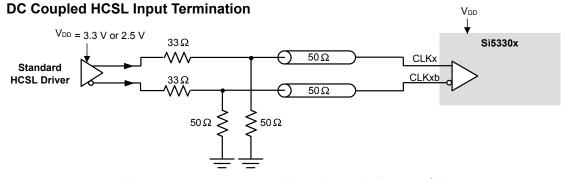
Figure 2.3. AC-Coupled, Single-Ended (LVCMOS) Input Termination



# **DC Coupled LVPECL Input Termination Scheme 2**







Note: 33 Ohm series termination is optional depending on the location of the receiver.

Figure 2.4. Differential DC-Coupled Input Terminations

Table 2.3. AC/DC-Coupled Clock Input Requirements for Glitchless, Non-Continuous Clocks 1, 2, 3

| Clock Input Type | Input Clock Driver Stop State |      |        |  |  |  |  |  |  |
|------------------|-------------------------------|------|--------|--|--|--|--|--|--|
| Clock Input Type | Low                           | High | High-Z |  |  |  |  |  |  |
| DC-Coupled       | Yes                           | Yes  | No     |  |  |  |  |  |  |
| AC-Coupled       | Yes                           | No   | No     |  |  |  |  |  |  |

#### Note:

- 1. "Non-continuous clocks" means any clock that can be stopped, disabled, or gapped.
- 2. "Yes" means this configuration is supported.
- 3. "No" indicates that the configuration is not supported. Operating under a "No" condition can result in erroneous clock outputs and/or erroneous LOS indications. Operating the device in unsupported configurations is not recommended.

#### 2.2 Internal Input Bias Resistors

Internal bias resistors ensure a differential output low condition in the event that the clock inputs are not connected. The clock input should not be actively driven when power is not applied to the device. The non-inverting input is biased with a 18.75 k $\Omega$  pull-down to GND and a 75 k $\Omega$  pull-up to V<sub>DD</sub>. The inverting input is biased with a 75 k $\Omega$  pull-up to V<sub>DD</sub>.

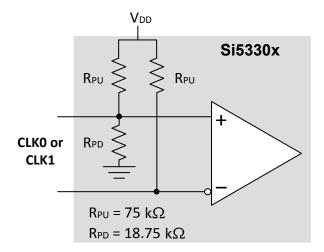


Figure 2.5. Internal Input Bias Resistors

#### 2.3 Voltage Reference (V<sub>REF</sub>)

The  $V_{REF}$  pin can be used to bias the input receiver, as shown in the figure below, when a single-ended input clock (such as LVCMOS) is used. Note that  $V_{REF} = V_{DD}/2$  and should be compatible with the Vcm rating of the single-ended input clock driving the CLK0 or CLK1 inputs. To optimize jitter and duty cycle performance, use the circuit in Figure 2.3 AC-Coupled, Single-Ended (LVCMOS) Input Termination on page 6.  $V_{REF}$  pin should be left floating when differential clocks are used.

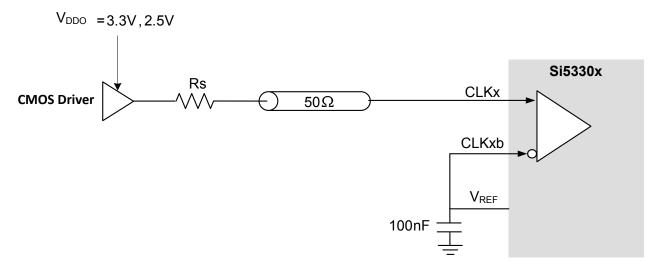


Figure 2.6. Using Voltage Reference with Single-Ended Input Clock

#### 2.4 Universal, Any-Format Output Buffer

The highly flexible output drivers support a wide range of clock signal formats, including LVPECL, low power LVPECL, LVDS, CML, HCSL, and LVCMOS. SFOUTx[1] and SFOUTx[0] are 3-level inputs that can be pinstrapped to select the Bank A and Bank B clock signal formats independently. This feature enables the device to be used for format/level translation in addition to clock distribution, minimizing the number of unique buffer part numbers required in a typical application and simplifying design reuse. For EMI reduction applications, four LVCMOS drive strength options are available for each V<sub>DDO</sub> setting.

| SFOUTx[1]         | SFOUTx[0]         | VDDOX = 3.3 V       | VDDOX = 2.5 V       | VDDOX = 1.8 V       |
|-------------------|-------------------|---------------------|---------------------|---------------------|
| Open <sup>1</sup> | Open <sup>1</sup> | LVPECL              | LVPECL              | N/A                 |
| 0                 | 0                 | LVDS                | LVDS                | LVDS                |
| 0                 | 1                 | LVCMOS, 24 mA drive | LVCMOS, 18 mA drive | LVCMOS, 12 mA drive |
| 1                 | 0                 | LVCMOS, 18 mA drive | LVCMOS, 12 mA drive | LVCMOS, 9 mA drive  |
| 1                 | 1                 | LVCMOS, 12 mA drive | LVCMOS, 9 mA drive  | LVCMOS, 6 mA drive  |
| Open <sup>1</sup> | 0                 | LVCMOS, 6 mA drive  | LVCMOS, 4 mA drive  | LVCMOS, 2 mA drive  |
| Open <sup>1</sup> | 1                 | LVPECL Low power    | LVPECL Low power    | N/A                 |
| 0                 | Open <sup>1</sup> | CML                 | CML                 | CML                 |
| 1                 | Open <sup>1</sup> | HCSL                | HCSL                | N/A                 |

Table 2.4. Output Signal Format Selection

#### Note

<sup>1.</sup> SFOUTx[1:0] are 3-level input pins. Tie low for "0" setting. Tie high for "1" setting. When left open, the pin is internally biased to  $V_{DD}/2$ .

#### 2.5 Input Mux (Si53301/02/04/05/07 Only)

The Si53301/02/04/05/07 provide two clock inputs for applications that need to select between one of two clock sources. The CLK\_SEL pin selects the active clock input and has an internal pulldown resistor. The following table summarizes the input and output clock based on the input mux pin settings.

Table 2.5. Input Mux Logic

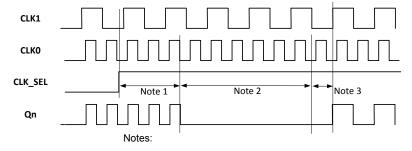
| CLK_SEL | CLK0 | CLK1 | Q <sup>1</sup> | Qb |
|---------|------|------|----------------|----|
| L       | L    | X    | L              | Н  |
| L       | Н    | X    | Н              | L  |
| Н       | X    | L    | L              | Н  |
| Н       | X    | Н    | Н              | L  |

#### Note:

1. On the next negative transition of CLK0 or CLK1.

#### 2.6 Glitchless Clock Input Switching

The Si53301/2/4/5/7 feature glitchless switching between two valid input clocks. The following figure illustrates that switching between input clocks does not generate runt pulses or glitches at the output.



- 1. Qn continues with CLK0 for 2-3 falling edges of CLK0.
- 2.  $\,Q_{n}\,\text{is}$  disabled low for 2-3 falling edges of CLK1 .
- 3.  $Q_n$  starts on the first rising edge after 1 + 2.

Figure 2.7. Glitchless Input Clock Switch

The Si53301/2/4/5/7 support glitchless switching between clock inputs with a frequency variance up to 10x. When a switchover to a new clock is made, the output will disable low after two or three clock cycles of the previously selected input clock. The outputs will remain low for up to three clock cycles of the newly-selected clock, after which the outputs will start from the newly-selected input. If a switchover to an absent clock is made, the output will glitchlessly stop low and wait for edges of the newly-selected clock. A switchover from an absent clock to a live clock will also be glitchless. Note that the CLK\_SEL input should not be toggled faster than 1/250th the frequency of the slower input clock.

## 2.7 Synchronous Output Enable

The Si5330x features a synchronous output enable (disable) feature. The output enable pin is sampled and synchronized to the falling edge of the input clock. This feature prevents runt pulses from being generated when the outputs are enabled or disabled.

When OE is low, Q is held low and Qb is held high for differential output formats. For LVCMOS output format options, both Q and Qb are held low when OE is set low. The output enable pin has an internal pull-up that enables the outputs when left unconnected. See Table 3.10 AC Characteristics on page 24 for output enable and output disable times.

#### 2.8 Loss of Signal (LOS) Indicator

Si53301/2/8 feature a Loss of Signal (LOS) indicator. The LOS0 and LOS1 indicators are used to check for the presence of input clocks CLK0 and CLK1. The LOS0 and LOS1 pins must be checked prior to selecting the clock input or should be polled to check for the presence of the currently selected input clock. In the event that an input clock is not present, the associated LOSx pin will assume a logic high (LOSx = 1) state. When a clock is present at the associated input clock pin, the LOSx pin will assume a logic low (LOSx = 0) state.

#### 2.9 Flexible Output Divider

The Si53301/02/03/08 provide optional clock division in addition to clock distribution. The divider setting for each bank of output clocks is selected via 3-level control pins as shown in the table below. Leaving the DIVx pins open will force a divider value of 1, which is the default mode of operation.

Table 2.6. Divider Selection

| DIVx <sup>1</sup> | Divider Value |
|-------------------|---------------|
| Open              | ÷1 (default)  |
| 0                 | ÷2            |
| 1                 | ÷4            |

#### Notes:

# 2.10 Power Supply (V<sub>DD</sub> and V<sub>DDOX</sub>)

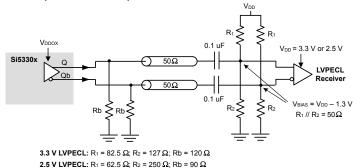
The device includes separate core ( $V_{DD}$ ) and output driver supplies ( $V_{DDOX}$ ). This feature allows the core to operate at a lower voltage than  $V_{DDO}$ , reducing current consumption in mixed supply applications. The core  $V_{DD}$  supports 3.3, 2.5, or 1.8 V. Control signals, such as CLK\_SEL, DIV, and OE, are in the VDD domain. Each output bank has its own  $V_{DDOX}$  supply, supporting 3.3, 2.5, or 1.8 V.

<sup>1.</sup> DIVx are 3-level input pins. Tie low for "0" setting. Tie high for "1" setting. When left open, the pin is internally biased to V<sub>DD</sub>/2.

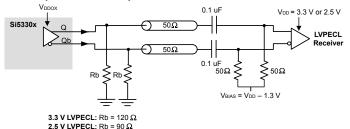
#### 2.11 Output Clock Termination Options

The recommended output clock termination options for ac and dc are shown below. Unused outputs should be left unconnected.

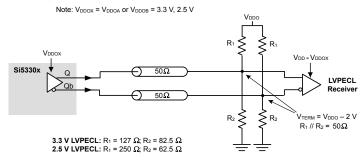
# **AC-Coupled LVPECL Output Termination Scheme 1**



#### **AC-Coupled LVPECL Output Termination Scheme 2**



#### **DC-Coupled LVPECL Output Termination Scheme 1**



## **DC-Coupled LVPECL Output Termination Scheme 2**

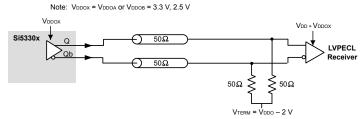
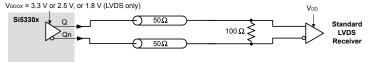
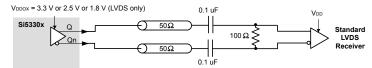


Figure 2.8. LVPECL AC and DC Output Terminations

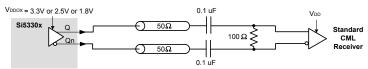
# DC Coupled LVDS and Low-Power LVPECL Termination



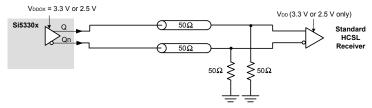
# AC Coupled LVDS and Low-Power LVPECL Termination



## AC Coupled CML Termination



#### **DC Coupled HCSL Receiver Termination**



#### **DC Coupled HCSL Source Termination**

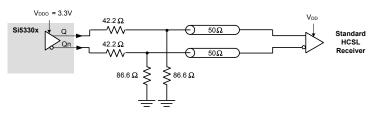


Figure 2.9. LVDS, CML, HCSL, and Low-Power LVPECL Output Terminations

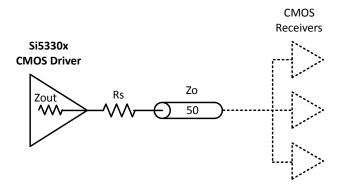


Figure 2.10. LVCMOS Output Termination

Table 2.7. Recommended LVCMOS R<sub>S</sub> Series Termination

| SFOUTX[1] | SFOUTX[0] | R <sub>S</sub> (Ω) |       |    |  |  |  |  |
|-----------|-----------|--------------------|-------|----|--|--|--|--|
|           |           | 3.3 V              | 1.8 V |    |  |  |  |  |
| 0         | 1         | 33                 | 33    | 33 |  |  |  |  |

| SFOUTX[1] | SFOUTX[0] | R <sub>S</sub> (Ω) |    |    |  |  |  |  |
|-----------|-----------|--------------------|----|----|--|--|--|--|
| 1         | 0         | 33                 | 33 | 33 |  |  |  |  |
| 1         | 1         | 33                 | 33 | 0  |  |  |  |  |
| Open      | 0         | 0                  | 0  | 0  |  |  |  |  |

# 2.12 LVCMOS Output Termination to Support 1.5 V and 1.2 V

LVCMOS clock outputs are natively supported at 1.8, 2.5, and 3.3 V. However, 1.2 V and 1.5 V LVCMOS clock outputs can be supported via a simple resistor divider network that will translate the buffer's 1.8 V output to a lower voltage as shown in the following figure.

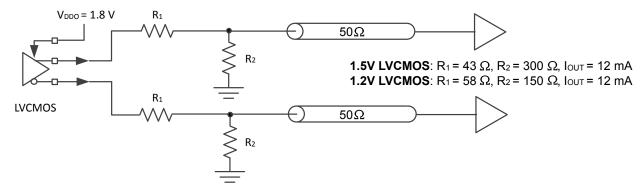


Figure 2.11. 1.5 V and 1.2 V LVCMOS Low-Voltage Output Termination

# 2.13 AC Timing Waveforms

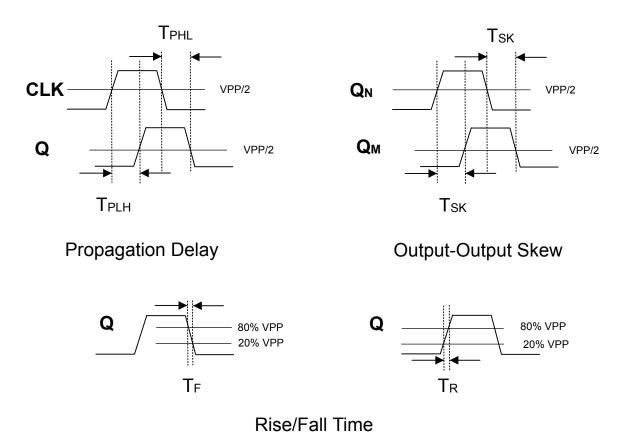


Figure 2.12. AC-Coupled Timing Waveforms

#### 2.14 Typical Phase Noise Performance (Differential Input Clock)

Each of the phase noise plots superimposes Source Jitter, Total SE Jitter, and Total Diff Jitter on the same diagram.

- · Source Jitter—Reference clock phase noise (measured Single-ended to PNA).
- Total Jitter (SE)—Combined source and clock buffer phase noise measured as a single-ended output to the phase noise analyzer and integrated from 12 kHz to 20 MHz.
- · Total Jitter (Diff)—Combined source and clock buffer phase noise measured as a differential output to the phase noise analyzer and integrated from 12 kHz to 20 MHz. The differential measurement as shown in each figure is made using a balun. For more information, see 3. Electrical Specifications.

Note: To calculate the total RMS phase jitter when adding a buffer to your clock tree, use the root-sum-square (RSS).

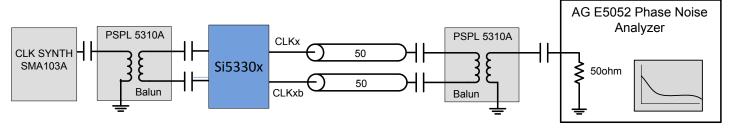
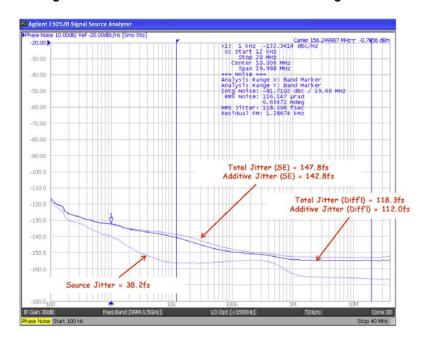
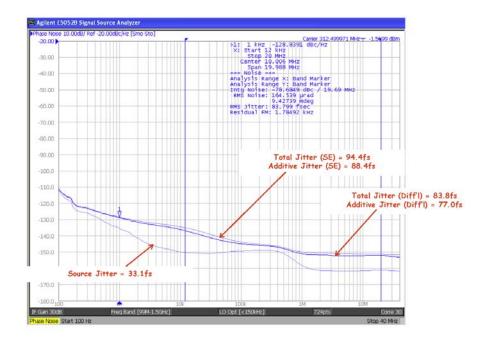


Figure 2.13. Differential Measurement Method Using a Balun



| Frequency | Differential           | Source Jitter | Total Jitter | Additive Jitter | Total Jitter        | Additive Jitter     |
|-----------|------------------------|---------------|--------------|-----------------|---------------------|---------------------|
| (MHz)     | Input Slew Rate (V/ns) | (fs)          | (SE) (fs)    | (SE) (fs)       | (Differential) (fs) | (Differential) (fs) |
| 156.25    | 1.0                    | 38.2          | 147.8        | 142.8           | 118.3               |                     |

Figure 2.14. Total Jitter Differential Input (156.25 MHz)



| Frequency | Differential           | Source Jitter | Total Jitter | Additive Jitter | Total Jitter        | Additive Jitter     |
|-----------|------------------------|---------------|--------------|-----------------|---------------------|---------------------|
| (MHz)     | Input Slew Rate (V/ns) | (fs)          | (SE) (fs)    | (SE) (fs)       | (Differential) (fs) | (Differential) (fs) |
| 312.5     | 1.0                    | 33.10         | 94.39        | 88.39           | 83.80               | 76.99               |

Figure 2.15. Total Jitter Differential Input (312.5 MHz)



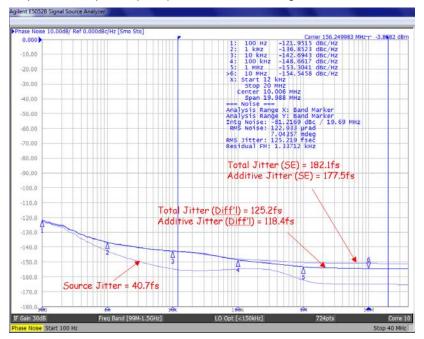
| Frequency<br>(MHz) | Differential<br>Input Slew Rate (V/ns) |    | Total Jitter<br>(SE) (fs) | Additive Jitter<br>(SE) (fs) | Total Jitter<br>(Differential) (fs) | Additive Jitter<br>(Differential) (fs) |
|--------------------|--|----|---------------------------|------------------------------|-------------------------------------|--|
| 625                | 1.0                                    | 23 | 57                        | 52                           | 59                                  | 54                                     |

Figure 2.16. Total Jitter Differential Input (625 MHz)

# 2.15 Typical Phase Noise Performance (Single-Ended Input Clock)

For single-ended phase noise measurements, the phase noise analyzer was connected directly without the use of a balun.

The following figure shows three phase noise plots superimposed on the same diagram.



| Frequency | Single-Ended           | Source Jitter | Total Jitter | Additive Jitter | Total Jitter        | Additive Jitter     |
|-----------|------------------------|---------------|--------------|-----------------|---------------------|---------------------|
| (MHz)     | Input Slew Rate (V/ns) | (fs)          | (SE) (fs)    | (SE) (fs)       | (Differential) (fs) | (Differential) (fs) |
| 156.25    | 1.0                    | 40.74         | 182.12       | 177.51          | 125.22              |                     |

Figure 2.17. Total Jitter Single-Ended Input (156.25 MHz)

#### 2.16 Input Mux Noise Isolation

The input clock mux is designed to minimize crosstalk between CLK0 and CLK1. This improves phase jitter performance when clocks are present at both the CLK0 and CLK1 inputs. The following figure shows a measurement of the input mux's noise isolation.

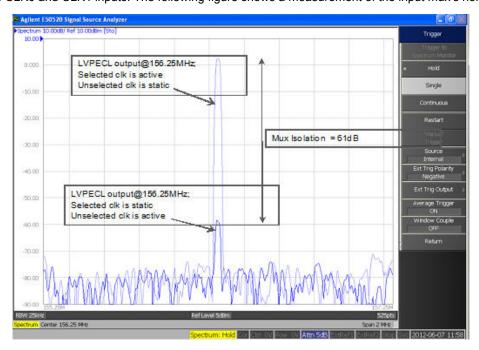


Figure 2.18. Input Mux Noise Isolation (Differential Input Clock, 44-QFN Package)

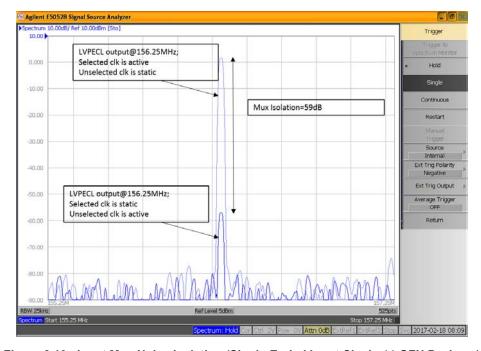


Figure 2.19. Input Mux Noise Isolation (Single-Ended Input Clock, 44-QFN Package)

### 2.17 Power Supply Noise Rejection

The device supports on-chip supply voltage regulation to reject power supply noise and simplify low-jitter operation in real-world environments. This feature enables robust operation alongside FPGAs, ASICs and SoCs and may reduce board-level filtering requirements. See *AN491: Power Supply Rejection for Low-Jitter Clocks* for more information.

# 3. Electrical Specifications

**Table 3.1. Recommended Operating Conditions** 

| Parameter                                 | Symbol                    | Test Condition            | Min  | Тур             | Max  | Unit |
|---|---------------------------|---------------------------|------|-----------------|------|------|
| Ambient Operating Temperature             | T <sub>A</sub>            |                           | -40  | _               | 85   | °C   |
|   |                           |                           | 1.71 | 1.8             | 1.89 | V    |
|   |                           | LVDS, CML                 | 2.38 | 2.5             | 2.63 | V    |
| Supply Voltage Dange1                     | V <sub>DD</sub>           |                           | 2.97 | 3.3             | 3.63 | V    |
| Supply Voltage Range <sup>1</sup>         | LVPECL, low power LVPECL, | 2.38                      | 2.5  | 2.63            | V    |      |
|   |                           | LVCMOS                    | 2.97 | 3.3             | 3.63 | V    |
|   |                           | HCSL                      | 2.97 | 2.97 3.3 3.63 V | V    |      |
|   |                           |                           | 1.71 | 1.8             | 1.89 | V    |
|   |                           | LVDS, CML, LVCMOS         | 2.38 | 2.5             | 2.63 | V    |
| 0.10.10.50.00.10.10.10.1                  | V                         |                           | 2.97 | 3.3             | 3.63 | V    |
| Output Buffer Supply Voltage <sup>1</sup> | V <sub>DDOX</sub>         | LVPECL, low power LVPECL, | 2.38 | 2.5             | 2.63 | V    |
|   |                           | LVCMOS                    | 2.97 | 3.3             | 3.63 | V    |
|   |                           | HCSL                      | 2.97 | 3.3             | 3.63 | V    |

# Note:

# **Table 3.2. Input Clock Specifications**

 $(V_{DD}$ =1.8 V ± 5%, 2.5 V ± 5%, or 3.3 V ± 10%,  $T_A$ = -40 to 85 °C)

| Parameter                                 | Symbol          | Test Condition                            | Min                   | Тур | Max                   | Unit |
|---|-----------------|---|-----------------------|-----|-----------------------|------|
| Differential Input Common<br>Mode Voltage | V <sub>CM</sub> | V <sub>DD</sub> = 2.5 V ± 5%, 3.3 V ± 10% | 0.05                  | _   | _                     | V    |
| Differential Input Swing (peak-to-peak)   | V <sub>IN</sub> |   | 0.2                   | _   | 2.2                   | V    |
| LVCMOS Input High Voltage                 | V <sub>IH</sub> | V <sub>DD</sub> = 2.5 V ± 5%, 3.3 V ± 10% | V <sub>DD</sub> × 0.7 | _   | _                     | V    |
| LVCMOS Input Low Voltage                  | V <sub>IL</sub> | V <sub>DD</sub> = 2.5 V ± 5%, 3.3 V ± 10% | _                     | _   | V <sub>DD</sub> × 0.3 | V    |
| Input Capacitance                         | C <sub>IN</sub> | CLK0 and CLK1 pins with respect to GND    | _                     | 5   | _                     | pF   |

<sup>1.</sup> Core supply  $V_{DD}$  and output buffer supplies  $V_{DDO}$  are independent. LVCMOS clock input is not supported for  $V_{DD}$  = 1.8 V but is supported for LVCMOS clock output for  $V_{DDOX}$  = 1.8 V. LVCMOS outputs at 1.5 V and 1.2 V can be supported via a simple resistor divider network.

<sup>2.</sup> See 2.12 LVCMOS Output Termination to Support 1.5 V and 1.2 V.

# **Table 3.3. DC Common Characteristics**

 $(V_{DD}$  = 1.8 V ± 5%, 2.5 V ± 5%, or 3.3 V ± 10%,  $T_A$  = -40 to 85 °C)

| Parameter                                | Symbol            | Test Condition  | Min                    | Тур                   | Max                        | Unit |
|--|-------------------|---|------------------------|-----------------------|----------------------------|------|
| Supply Current                           | I <sub>DD</sub>   |   | _                      | 65                    | 100                        | mA   |
|  |                   | LVPECL (3.3 V)<br>Si53301/2/3/4/5/6/8   | _                      | 35                    | _                          | mA   |
|  |                   | LVPECL (3.3 V) Si53307  | _                      | 40                    | _                          | mA   |
|  |                   | Low Power LVPECL (3.3 V)<br>Si53301/2/4/5/6/7/8   | _                      | 35                    | _                          | mA   |
|  |                   | Low Power LVPECL (3.3 V)<br>Si53303   | _                      | 30                    | _                          | mA   |
|  |                   | LVDS (3.3 V)  | _                      | 20                    | _                          | mA   |
|  |                   | CML (3.3V), Si53301/4/8   | _                      | 35                    | _                          | mA   |
|  |                   | CML (3.3V), Si53302/3/5   | _                      | 30                    | _                          | mA   |
| Output Buffer Supply Current             |                   | CML (3.3V), Si53306   | _                      | 40                    | _                          | mA   |
| (Per Clock Output)                       | I <sub>DDOX</sub> | CML (3.3V), Si53307   | _                      | 60                    | _                          | mA   |
| @ 100 MHz (differential) @ 200MHz (CMOS) | рох               | HCSL, 100 MHz, 2 pF load (3.3 V)  | _                      | 35                    | _                          | mA   |
|  |                   | CMOS (1.8 V, SFOUT = Open/0), per output, $C_L = 5 pF$ , 200 MHz                              | _                      | 5                     | _                          | mA   |
|  |                   | CMOS (2.5 V, SFOUT = Open/0), per output, C <sub>L</sub> = 5 pF, 200 MHz                      | _                      | 8                     | _                          | mA   |
|  |                   | CMOS (3.3 V, SFOUT = 0/1),<br>per output, $C_L$ = 5 pF, 200 MHz<br>Si53306/7                  | _                      | 20                    | _                          | mA   |
|  |                   | CMOS (3.3 V, SFOUT = 0/1),<br>per output, C <sub>L</sub> = 5 pF, 200 MHz<br>Si53301/2/3/4/5/8 | _                      | 15                    | -<br>-<br>-<br>-<br>-<br>- | mA   |
| Voltage Reference                        | V <sub>REF</sub>  | V <sub>REF</sub> pin, I <sub>REF</sub> = ±500 μA  | _                      | V <sub>DD</sub> /2    | _                          | V    |
| Innut High Valtage                       | V                 | SFOUTx, DIVx, CLK_SEL, OEx<br>Si53303   | 0.85 × V <sub>DD</sub> | _                     | _                          | V    |
| Input High Voltage                       | V <sub>IH</sub>   | SFOUTx, DIVx, CLK_SEL, OEx<br>Si53301/2/4/5/6/7/8   | 0.8 × V <sub>DD</sub>  | _                     | _                          | V    |
| Input Mid Voltage                        | V <sub>IM</sub>   | SFOUTx, DIVx<br>3-level input pins  | 0.45 × V <sub>DD</sub> | 0.5 × V <sub>DD</sub> | 0.55 × V <sub>DD</sub>     | V    |
| Input Low Voltage                        | V <sub>IL</sub>   | SFOUTx, DIVx, CLK_SEL, OEx<br>Si53301/2/4/5/6/7/8   | _                      | _                     | 0.2 × V <sub>DD</sub>      | V    |
| Input Low Voltage                        | VIL               | SFOUTx, DIVx, CLK_SEL, OEx<br>Si53303   | _                      | _                     | 0.15 × V <sub>DD</sub>     | V    |
| Output Voltage High (LOSx)               | V <sub>OH</sub>   | IDD = -1 mA   | 0.8 x V <sub>DD</sub>  | _                     | _                          | V    |
| Output Voltage Low (LOSx)                | V <sub>OL</sub>   | IDD = 1 mA  | _                      | _                     | 0.2 x V <sub>DD</sub>      | V    |
| Internal Pull-down Resistor              | R <sub>DOWN</sub> | CLK_SEL, DIVx, SFOUTx,  | _                      | 25                    | _                          | kΩ   |

| Parameter                 | Symbol          | Test Condition    | Min | Тур | Max | Unit |
|---------------------------|-----------------|-------------------|-----|-----|-----|------|
| Internal Pull-up Resistor | R <sub>UP</sub> | OEx, DIVx, SFOUTx | _   | 25  | _   | kΩ   |

# Table 3.4. Output Characteristics (LVPECL)

 $(V_{DDOX} = 2.5 \text{ V} \pm 5\%, \text{ or } 3.3 \text{ V} \pm 10\%, T_A = -40 \text{ to } 85 \text{ °C})$ 

| Parameter                        | Symbol           | Test Condition | Min                       | Тур  | Max                       | Unit |
|----------------------------------|------------------|----------------|---------------------------|------|---------------------------|------|
| Output DC Common Mode<br>Voltage | V <sub>COM</sub> |                | V <sub>DDOX</sub> – 1.595 | _    | V <sub>DDOX</sub> – 1.245 | V    |
| Single-Ended Output Swing        | V <sub>SE</sub>  |                | 0.55                      | 0.80 | 1.050                     | V    |

# Note:

# Table 3.5. Output Characteristics (Low Power LVPECL)

 $(V_{DDOX} = 2.5 \text{ V} \pm 5\%, \text{ or } 3.3 \text{ V} \pm 10\%, T_A = -40 \text{ to } 85 \text{ °C})$ 

| Parameter                     | Symbol           | Test Condition                             | Min                       | Тур  | Max                       | Unit |
|-------------------------------|------------------|--|---------------------------|------|---------------------------|------|
| Output DC Common Mode Voltage | V <sub>COM</sub> | R <sub>L</sub> = 100 Ω across Qn<br>and Qn | V <sub>DDOX</sub> – 1.895 |      | V <sub>DDOX</sub> – 1.275 | V    |
| Single-Ended Output Swing     | V <sub>SE</sub>  | R <sub>L</sub> = 100 Ω across Qn<br>and Qn | 0.25                      | 0.60 | 0.85                      | V    |

# Table 3.6. Output Characteristics (CML)

 $(V_{DDOX} = 1.8 \text{ V} \pm 5\%, 2.5 \text{ V} \pm 5\%, \text{ or } 3.3 \text{ V} \pm 10\%, T_A = -40 \text{ to } 85 ^{\circ}\text{C})$ 

| Parameter                 | Symbol          | Test Condition  | Min | Тур | Max | Unit |
|---------------------------|-----------------|---|-----|-----|-----|------|
| Single-Ended Output Swing | V <sub>SE</sub> | Terminated as shown in Figure 2.9 LVDS, CML, HCSL, and Low-Power LVPECL Output Terminations on page 13 (CML termination). | 300 | 400 | 550 | mV   |

<sup>1.</sup> Unused outputs can be left floating. Do not short unused outputs to ground.

Table 3.7. Output Characteristics (LVDS)

 $(V_{DDOX} = 1.8 \text{ V} \pm 5\%, 2.5 \text{ V} \pm 5\%, \text{ or } 3.3 \text{ V} \pm 10\%, T_A = -40 \text{ to } 85 ^{\circ}\text{C})$ 

| Parameter  | Symbol            | Test Condition   | Min  | Тур  | Max  | Unit |
|--|-------------------|--|------|------|------|------|
| Single Ended Output Swing  | V <sub>SE</sub>   | $R_L$ = 100 Ω across $Q_N$ and $Q_N$<br>Si53301/2/4/5/6/7/8  | 247  | _    | 490  | mV   |
| Single-Ended Output Swing  |                   | $R_L$ = 100 $\Omega$ across $Q_N$ and $Q_N$ Si53303  | 247  | _    | 454  | mV   |
| Output Common Mode Voltage<br>(V <sub>DDO</sub> = 2.5 V or 3.3V) | V <sub>COM1</sub> | $V_{DDOX}$ = 2.38 to 2.63 V, 2.97 to 3.63 V, $R_L$ = 100 $\Omega$ across $Q_N$ and $Q_N$                         | 1.10 | 1.25 | 1.35 | V    |
| Output Common Mode Voltage                                       | V <sub>COM2</sub> | $V_{DDOX}$ = 1.71 to 1.89 V, R <sub>L</sub> = 100 Ω across Q <sub>N</sub> and Q <sub>N</sub> Si53301/2/4/5/6/7/8 | 0.85 | 0.97 | 1.25 | V    |
| (V <sub>DDO</sub> = 1.8 V)                                       |                   | $V_{DDOX}$ = 1.71 to 1.89 V, $R_L$ = 100 Ω across $Q_N$ and $Q_N$ Si53303  | 0.85 | 0.97 | 1.1  | V    |

# Table 3.8. Output Characteristics (LVCMOS)

 $(V_{DDOX} = 1.8 \text{ V} \pm 5\%, 2.5 \text{ V} \pm 5\%, \text{ or } 3.3 \text{ V} \pm 10\%, T_A = -40 \text{ to } 85 ^{\circ}\text{C})$ 

| Parameter           | Symbol          | Test Condition      | Min                      | Тур | Max                      | Unit |
|---------------------|-----------------|---------------------|--------------------------|-----|--------------------------|------|
| Output Valtage High | Vall            | Si53301/2/4/5/6/7/8 | 0.75 × V <sub>DDOX</sub> | _   | _                        | V    |
| Output Voltage High | V <sub>OH</sub> | Si53303             | 0.8 × V <sub>DDOX</sub>  | _   | _                        | V    |
| Outrot Valtaga I am | V <sub>OL</sub> | Si53301/2/4/5/6/7/8 | _                        | _   | 0.25 × V <sub>DDOX</sub> | V    |
| Output Voltage Low  |                 | Si53303             | _                        | _   | 0.2 × V <sub>DDOX</sub>  | V    |

#### Note:

#### Table 3.9. Output Characteristics (HCSL)

 $(V_{DDOX} = 2.5 \text{ V} \pm 5\% \text{ or } 3.3 \text{ V} \pm 10\%, T_A = -40 \text{ to } 85 ^{\circ}\text{C}))$ 

| Parameter                 | Symbol          | Test Condition  | Min  | Тур | Max | Unit |
|---------------------------|-----------------|---|------|-----|-----|------|
| Output Voltago High       | Vall            | $R_L = 50 \Omega \text{ to GND}$<br>Si53301/2/3/4/5/6/8 | 550  | 700 | 900 | mV   |
| Output Voltage High       | V <sub>OH</sub> | $R_L = 50 \Omega \text{ to GND}$<br>Si53307             | 550  | 700 | 850 | mV   |
| Output Voltage Low        | V <sub>OL</sub> | $R_L$ = 50 $\Omega$ to GND                              | -150 | 0   | 150 | mV   |
| Single-Ended Output Swing | V <sub>SE</sub> | $R_L$ = 50 $\Omega$ to GND                              | 550  | 700 | 850 | mV   |
| Crossing Voltage          | V <sub>C</sub>  | $R_L$ = 50 $\Omega$ to GND                              | 250  | 350 | 550 | mV   |

<sup>1.</sup> I<sub>OH</sub> and I<sub>OL</sub> per the Output Signal Format Table for specific V<sub>DDOX</sub> and SFOUTx settings.

# Table 3.10. AC Characteristics

 $(V_{DD} = V_{DDOX} = 1.8 \text{ V} \pm 5\%, 2.5 \text{ V} \pm 5\%, \text{ or } 3.3 \text{ V} \pm 10\%, T_A = -40 \text{ to } 85 \text{ °C})$ 

| Parameter                                  | Symbol                             | Test Condition   | Min  | Тур                   | Max  | Unit |
|--|------------------------------------|--|------|-----------------------|------|------|
| LOO: Ola an Tima                           | т                                  | F < 100 MHz  | _    | T <sub>PER</sub> + 15 | _    | ns   |
| LOSx Clear Time                            | T <sub>LOSCLR</sub>                | F > 100 MHz  | _    | 25                    | _    | ns   |
| LOSx Activation Time                       | T <sub>LOSACT</sub>                |  | _    | 15                    | _    | μs   |
| Frequency                                  | F                                  | LVPECL, low power LVPECL,<br>LVDS, CML, HCSL <sup>1</sup>                            | 1    | _                     | 725  | MHz  |
| . ,  |                                    | LVCMOS   | 1    | _                     | 200  | MHz  |
| Duty Cycle <sup>6</sup>                    | Dc                                 | 200 MHz, 20/80% T <sub>R</sub> /T <sub>F</sub> <10% of period (LVCMOS) (12 mA drive) | 40   | 50                    | 60   | %    |
|  |                                    | 80% T <sub>R</sub> /T <sub>F</sub> <10% of period<br>(Differential)                  | 48   | 50                    | 52   | %    |
| Minimum Input Clock Slew Rate <sup>5</sup> | SR                                 | Required to meet prop delay and additive jitter specifications (20–80%)              | 0.75 | _                     | _    | V/ns |
|  |                                    | LVDS, 20/80%   | _    | _                     | 325  | ps   |
|  | T <sub>R</sub> /T <sub>F</sub>     | LVPECL, 20/80%   | _    | _                     | 350  | ps   |
|  |                                    | HCSL <sup>1</sup> , 20/80%   | _    | _                     | 280  | ps   |
| Output Rise/Fall Time                      |                                    | CML, 20/80%  | _    | _                     | 350  | ps   |
|  |                                    | Low-Power LVPECL, 20/80%   | _    | _                     | 350  | ps   |
|  |                                    | LVCMOS 200 MHz, 20/80%,<br>2 pF load   | _    | _                     | 750  | ps   |
| Minimum Input Pulse Width                  | T <sub>W</sub>                     |  | 500  | _                     | _    | ps   |
|  |                                    | LVCMOS<br>(12 mA drive with no load)   | 1250 | 2000                  | 2750 | ps   |
|  |                                    | LVPECL<br>Si53301/2/3/4/5/8  | 600  | 800                   | 1000 | ps   |
| Propagation Delay                          | T <sub>PLH,</sub> T <sub>PHL</sub> | LVPECL<br>Si53306/7  | 675  | 875                   | 1075 | ps   |
|  |                                    | LVDS<br>Si53301/2/3/4/5/8  | 600  | 800                   | 1000 | ps   |
|  |                                    | LVDS<br>Si53306/7  | 675  | 875                   | 1075 | ps   |
|  |                                    | F = 1 MHz  | _    | 2500                  | _    | ns   |
| Output Enable Time<br>Si53301/2/4/5/8      | T <sub>EN</sub>                    | F = 100 MHz  | _    | 30                    | _    | ns   |
|  |                                    | F = 725 MHz  | _    | 5                     | _    | ns   |
|  |                                    | F = 1 MHz  |      | 2000                  | _    | ns   |
| Output Enable Time<br>Si53303              | T <sub>EN</sub>                    | F = 100 MHz  | _    | 60                    | _    | ns   |
|  |                                    | F = 725 MHz  | _    | 50                    | _    | ns   |

| Parameter                                 | Symbol          | Test Condition                                  | Min | Тур        | Max | Unit |
|---|-----------------|---|-----|------------|-----|------|
|   |                 | F = 1 MHz                                       | _   | 1570       | _   | ns   |
| Output Enable Time<br>Si53306/7           | $T_{EN}$        | F = 100 MHz                                     | _   | 20         | _   | ns   |
|   |                 | F = 725 MHz                                     | _   | 5          | _   | ns   |
|   |                 | F = 1 MHz                                       | _   | 2000       | _   | ns   |
| Output Disable Time<br>Si53301/2/4/5/8    | $T_{DIS}$       | F = 100 MHz                                     | _   | 30         | _   | ns   |
| 0.0000 1/2/ 1/0/0                         |                 | F = 725 MHz                                     | _   | 5          | _   | ns   |
|   |                 | F = 1 MHz                                       | _   | 2000       | _   | ns   |
| Output Disable Time<br>Si53303            | $T_{DIS}$       | F = 100 MHz                                     | _   | 25         | _   | ns   |
|   |                 | F = 725 MHz                                     | _   | 15         | _   | ns   |
|   |                 | F = 1 MHz                                       | _   | 2000       | _   | ns   |
| Output Disable Time<br>Si53306/7          | $T_{DIS}$       | F = 100 MHz                                     | _   | 35         | _   | ns   |
| 0.0000077                                 |                 | F = 725 MHz                                     | _   | 5          | _   | ns   |
|   |                 | LVCMOS<br>(12 mA drive to no load) <sup>7</sup> | _   | 50         | 120 | ps   |
| Output to Output Skew <sup>2</sup>        | T <sub>SK</sub> | LVPECL  | _   | 35         | 75  | ps   |
|   |                 | LVDS  | _   | 35         | 85  | ps   |
| Part to Part Skew <sup>3</sup>            | T <sub>PS</sub> | Differential                                    | _   | _          | 150 | ps   |
|   | PSNR            | 10 kHz sinusoidal noise                         | _   | -63        | _   | dBc  |
| Power Supply Noise Rejection <sup>4</sup> |                 | 100 kHz sinusoidal noise                        | _   | -62        | _   | dBc  |
| (Si53305/2)                               |                 | 500 kHz sinusoidal noise                        | _   | -58        | _   | dBc  |
|   |                 | 10 MHz sinusoidal noise                         | _   | -55        | _   | dBc  |
|   |                 | 10 kHz sinusoidal noise                         | _   | -65        | _   | dBc  |
| Power Supply Noise Rejection <sup>4</sup> | DONE            | 100 kHz sinusoidal noise                        | _   | -63        | _   | dBc  |
| (Si53308/4/1)                             | PSNR            | 500 kHz sinusoidal noise                        | _   | -60        | _   | dBc  |
|   |                 | 10 MHz sinusoidal noise                         | _   | -55        | _   | dBc  |
|   |                 | 10 kHz sinusoidal noise                         | _   | -72        | _   | dBc  |
| Power Supply Noise Rejection <sup>4</sup> | DONE            | 100 kHz sinusoidal noise                        | _   | <b>-70</b> | _   | dBc  |
| (Si53307/6)                               | PSNR            | 500 kHz sinusoidal noise                        | _   | -67        | _   | dBc  |
|   |                 | 10 MHz sinusoidal noise                         | _   | -62        | _   | dBc  |
|   |                 | 10 kHz sinusoidal noise                         | _   | -90        | _   | dBc  |
| Power Supply Noise Rejection <sup>4</sup> | DOME            | 100 kHz sinusoidal noise                        | _   | -90        | _   | dBc  |
| (Si53303)                                 | PSNR            | 500 kHz sinusoidal noise                        | _   | -80        | _   | dBc  |
|   |                 | 10 MHz sinusoidal noise                         | _   | -70        | _   | dBc  |

|     | Parameter | Symbol | Test Condition | Min | Тур | Max | Unit |
|-----|-----------|--------|----------------|-----|-----|-----|------|
| - 1 |           |        |                |     |     |     |      |

#### Notes:

- 1. HCSL measurements were made with receiver termination and applies for 2.5 V and 3.3 V only. See Figure 2.9 LVDS, CML, HCSL, and Low-Power LVPECL Output Terminations on page 13.
- 2. Output to Output skew specified for outputs with an identical configuration.
- 3. Defined as skew between any output on different devices operating at the same supply voltage, temperature, and equal load condition. Using the same type of inputs on each device, the outputs are measured at the differential cross points.
- 4. Measured for 156.25 MHz carrier frequency. Sine-wave noise added to V<sub>DDOX</sub> (3.3 V = 100 mV<sub>PP</sub>) and noise spur amplitude measured. See "AN491: Power Supply Rejection for Low-Jitter Clocks" for further details.
- 5. TBD
- 6.50% input duty cycle.
- 7. LVCMOS outputs are in phase.

Table 3.11. Additive Jitter, Differential Clock Input

|                 | 1                                 | Output       | Additive Jitter   |   |              |     |     |  |  |  |
|-----------------|-----------------------------------|--------------|---|---|--------------|-----|-----|--|--|--|
|                 | Input <sup>1</sup> , <sup>2</sup> | Output       |   | (fs rms, 12 kHz to 20 MHz) <sup>3</sup>     |              |     |     |  |  |  |
| V <sub>DD</sub> | Freq<br>(MHz)                     | Clock Format | Amplitude<br>V <sub>IN</sub><br>(Single-Ended,<br>Peak-to-Peak) | Differential<br>20%-80% Slew<br>Rate (V/ns) | Clock Format | Тур | Max |  |  |  |
| 3.3             | 725                               | Differential | 0.15  | 0.637                                       | LVPECL       | 45  | 65  |  |  |  |
| 3.3             | 725                               | Differential | 0.15  | 0.637                                       | LVDS         | 50  | 65  |  |  |  |
| 3.3             | 156.25                            | Differential | 0.5   | 0.458                                       | LVPECL       | 160 | 185 |  |  |  |
| 3.3             | 156.25                            | Differential | 0.5   | 0.458                                       | LVDS         | 150 | 200 |  |  |  |
| 2.5             | 725                               | Differential | 0.15  | 0.637                                       | LVPECL       | 45  | 65  |  |  |  |
| 2.5             | 725                               | Differential | 0.15  | 0.637                                       | LVDS         | 50  | 65  |  |  |  |
| 2.5             | 156.25                            | Differential | 0.5   | 0.458                                       | LVPECL       | 145 | 185 |  |  |  |
| 2.5             | 156.25                            | Differential | 0.5   | 0.458                                       | LVDS         | 145 | 195 |  |  |  |

#### Notes:

- 1. For best additive jitter results, use the fastest slew rate possible. See "AN766: Understanding and Optimizing Clock Buffer's Additive Jitter Performance" for more information.
- 2. AC-coupled differential inputs.
- 3. Measured differentially using a balun at the phase noise analyzer input. See Figure 2.13 Differential Measurement Method Using a Balun on page 16.

Table 3.12. Additive Jitter, Single-Ended Clock Input

|                 | Input <sup>1</sup> , <sup>2</sup> Output |              | Additive Jitter   |   |   |     |     |  |
|-----------------|--|--------------|---|---|---|-----|-----|--|
| V <sub>DD</sub> | Freq<br>(MHz)                            | Clock Format | Amplitude<br>V <sub>IN</sub><br>(single-ended,<br>peak to peak) | (fs rms, 12 k<br>SE 20%-80% Slew<br>Rate (V/ns) | (Hz to 20 MHz) <sup>3</sup><br>Clock Format | Тур | Max |  |
| 3.3             | 200                                      | Single-ended | 1.70  | 1   | LVCMOS4                                     | 120 | 160 |  |
| 3.3             | 156.25                                   | Single-ended | 2.18  | 1   | LVPECL                                      | 160 | 185 |  |
| 3.3             | 156.25                                   | Single-ended | 2.18  | 1   | LVDS  | 150 | 200 |  |
| 3.3             | 156.25                                   | Single-ended | 2.18  | 1   | LVCMOS4                                     | 130 | 180 |  |
| 2.5             | 200                                      | Single-ended | 1.70  | 1   | LVCMOS <sup>5</sup>                         | 120 | 160 |  |
| 2.5             | 156.25                                   | Single-ended | 2.18  | 1   | LVPECL                                      | 145 | 185 |  |
| 2.5             | 156.25                                   | Single-ended | 2.18  | 1   | LVDS  | 145 | 195 |  |
| 2.5             | 156.25                                   | Single-ended | 2.18  | 1   | LVCMOS <sup>5</sup>                         | 140 | 180 |  |

#### Notes:

- 1. For best additive jitter results, use the fastest slew rate possible. See "AN766: Understanding and Optimizing Clock Buffer's Additive Jitter Performance" for more information.
- 2. DC-coupled single-ended inputs.
- 3. Measured single-ended at the phase noise analyzer input. See Figure 2.17 Total Jitter Single-Ended Input (156.25 MHz) on page 18.
- 4. Drive Strength: 12 mA, 3.3 V (SFOUT = 11). LVCMOS jitter is measured single-ended.
- 5. Drive Strength: 9 mA, 2.5 V (SFOUT = 11). LVCMOS jitter is measured single-ended.

**Table 3.13. Thermal Conditions** 

| Package                   | Parameter                               | Symbol        | Test Condition | Value | Unit |
|---------------------------|---|---------------|----------------|-------|------|
|                           | Thermal Resistance, Junction to Ambient | $\theta_{JA}$ | Still air      | 60    | °C/W |
| 3 x 3 mm QFN <sup>1</sup> | Thermal Resistance, Junction to Case    | $\theta_{JC}$ | Still air      | 10.8  | °C/W |
|                           | Thermal Resistance, Junction to Board   | $\theta_{JB}$ | Still air      | 34.1  | °C/W |
|                           | Thermal Resistance, Junction to Ambient | $\theta_{JA}$ | Still air      | 50.3  | °C/W |
| 5 x 5 mm QFN <sup>2</sup> | Thermal Resistance, Junction to Case    | $\theta_{JC}$ | Still air      | 10.3  | °C/W |
|                           | Thermal Resistance, Junction to Board   | $\theta_{JB}$ | Still air      | 30.9  | °C/W |
|                           | Thermal Resistance, Junction to Ambient | $\theta_{JA}$ | Still air      | 46.2  | °C/W |
| 7 x 7 mm QFN <sup>3</sup> | Thermal Resistance, Junction to Case    | $\theta_{JC}$ | Still air      | 27.1  | °C/W |
|                           | Thermal Resistance, Junction to Board   | $\theta_{JB}$ | Still air      | 28    | °C/W |

#### Note:

- 1. Based on a 2-layer, PCB with Dimension 3"x4.5". PCB Thickness of 1.6mm. PCB Center Land with 4 Via to backside, 75% Cu coverage.
- 2. Based on PCB with dimension 3" x 4.5", PCB Thickness of 1.6 mm. PCB Center Land with 4 Via to top plane.
- 3. Based on 2-layer PCB with dimension 3" x 4.5", PCB Thickness of 1.6 mm. PCB Center Land with 16 Via to back side with 75% Cu coverage.

**Table 3.14. Absolute Maximum Ratings** 

| Parameter                            | Symbol            | Test Condition                                     | Min         | Тур | Max                   | Unit |
|--------------------------------------|-------------------|--|-------------|-----|-----------------------|------|
| Storage Temperature                  | T <sub>S</sub>    |  | <b>–</b> 55 | _   | 150                   | °C   |
| Supply Voltage                       | $V_{DD}$          |  | -0.5        | _   | 3.8                   | V    |
| Input Voltage                        | V <sub>IN</sub>   |  | -0.5        | _   | V <sub>DD</sub> + 0.3 | V    |
| Output Voltage                       | V <sub>OUT</sub>  |  | _           | _   | V <sub>DD</sub> + 0.3 | V    |
| ESD Sensitivity                      | HBM               | HBM, 100 pF, 1.5 kΩ                                | _           | _   | 2000                  | V    |
| ESD Sensitivity                      | CDM               |  | _           | _   | 500                   | V    |
| Peak Soldering Reflow<br>Temperature | T <sub>PEAK</sub> | Pb-Free; Solder reflow profile per JEDEC J-STD-020 | _           | _   | 260                   | °C   |
| Maximum Junction<br>Temperature      | TJ                |  | _           | _   | 125                   | °C   |

### Note:

1. Stresses beyond those listed in this table may cause permanent damage to the device. Functional operation specification compliance is not implied at these conditions. Exposure to maximum rating conditions for extended periods may affect device reliability.

# 4. Detailed Block Diagrams

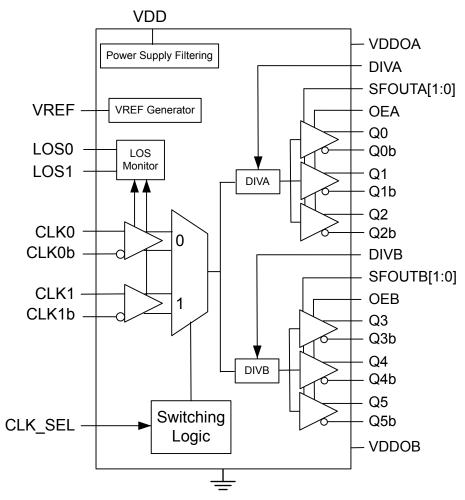


Figure 4.1. Si53301 Block Diagram

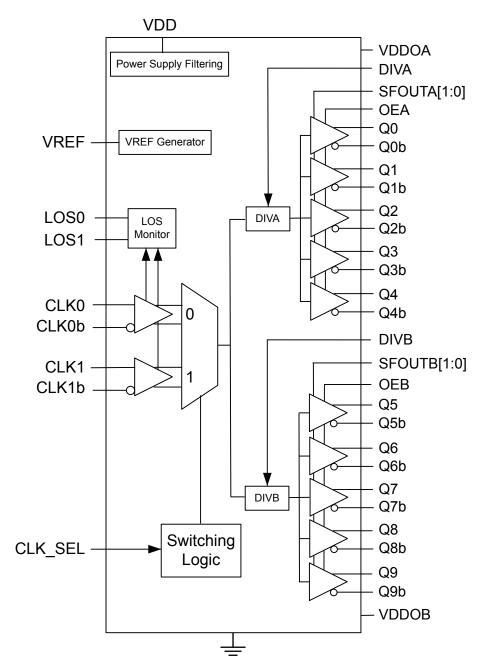


Figure 4.2. Si53302 Block Diagram

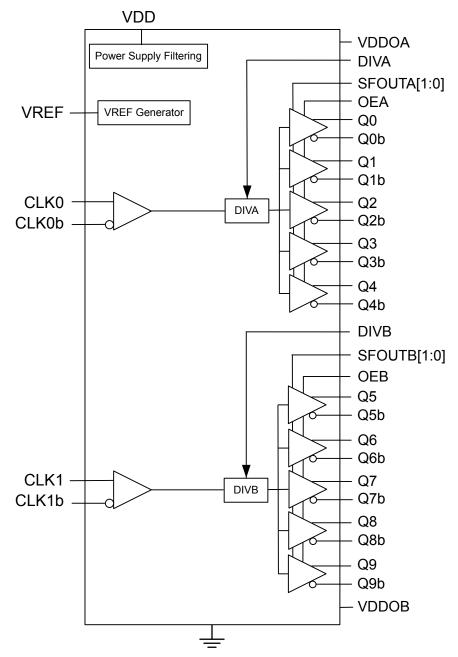


Figure 4.3. Si53303 Block Diagram

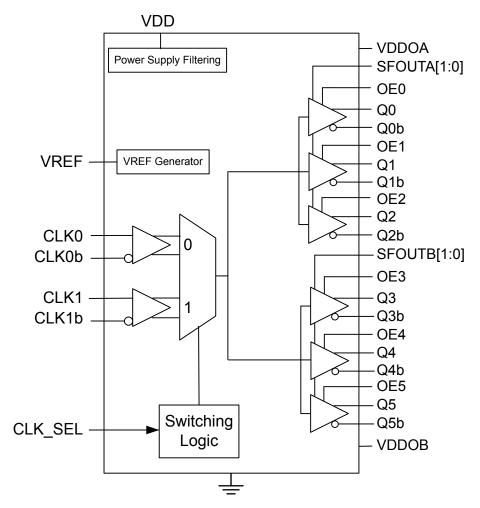


Figure 4.4. Si53304 Block Diagram

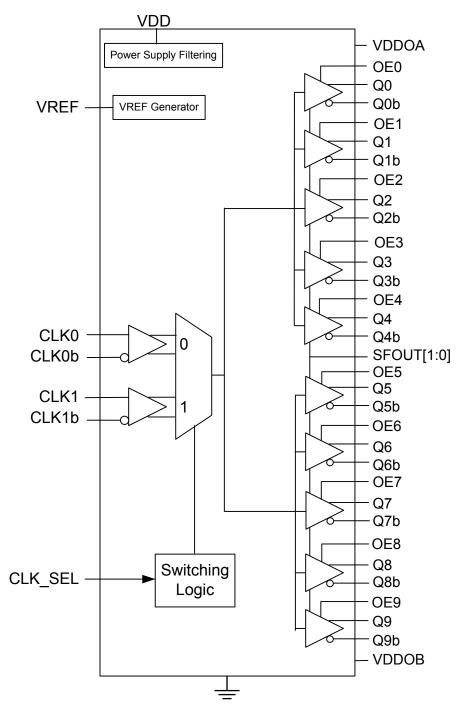


Figure 4.5. Si53305 Block Diagram

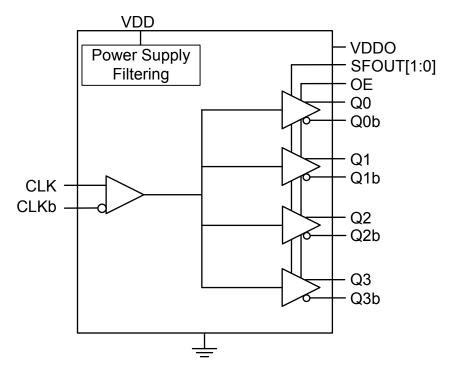


Figure 4.6. Si53306 Block Diagram

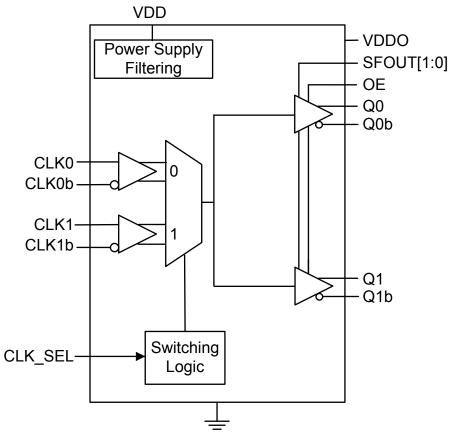


Figure 4.7. Si53307 Block Diagram

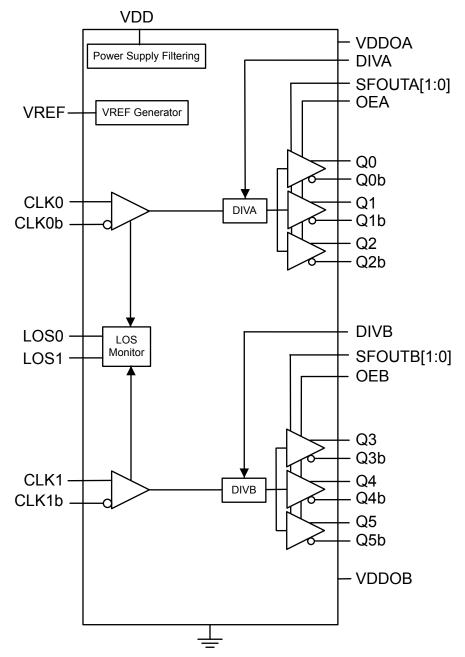


Figure 4.8. Si53308 Block Diagram

# 5. Pin Descriptions

# 5.1 Si53301 Pin Descriptions

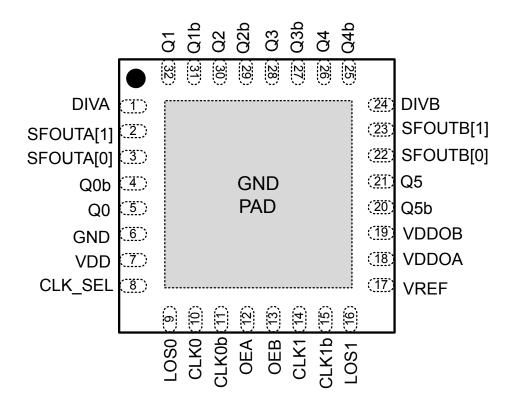


Table 5.1. Si53301 -QFN Pin Descriptions

| Pin | Name      | Type <sup>1</sup> | Description   |
|-----|-----------|-------------------|---|
|     |           |                   | Output divider control pin for Bank A   |
| 1   | DIVA      | I                 | Three-level input control. Internally biased at $V_{DD}/2$ . Can be left floating or tied to ground or $V_{DD}$ . |
|     |           |                   | Output signal format control pin for Bank A   |
| 2   | SFOUTA[1] | I                 | Three-level input control. Internally biased at $V_{DD}/2$ . Can be left floating or tied to ground or $V_{DD}$ . |
|     |           |                   | Output signal format control pin for Bank A   |
| 3   | SFOUTA[0] | I                 | Three-level input control. Internally biased at $V_{DD}/2$ . Can be left floating or tied to ground or $V_{DD}$ . |
| 4   | Q0b       | 0                 | Output clock 0 (complement)   |
| 5   | Q0        | 0                 | Output clock 0  |
| 6   | GND       | GND               | Ground  |
| 7   | VDD       | Р                 | Core voltage supply. Bypass with 1.0 µF capacitor placed as close to the VDD pin as possible.                     |

| Pin | Name      | Type <sup>1</sup> | Description   |
|-----|-----------|-------------------|---|
|     |           |                   | Mux input select pin  |
|     |           |                   | Clock inputs are switched without the introduction of glitches.   |
| 8   | CLK_SEL   | ı                 | When CLK_SEL is high, CLK1 is selected.   |
|     |           |                   | When CLK_SEL is low, CLK0 is selected.  |
|     |           |                   | CLK_SEL contains an internal pull-down resistor.  |
|     |           |                   | The LOS0 status pin indicates whether a clock is present at the CLK0 input.                                       |
| 9   | LOS0      | 0                 | CLK0 input clock present LOS0 = 0   |
|     |           |                   | CLK0 input clock not present LOS0 = 1   |
| 10  | CLK0      | I                 | Input clock 0   |
| 11  | CLK0b     |                   | Input clock 0 (complement)  |
|     | CLROD     | <b>'</b>          | When the CLK0 is driven by a single-end input, connect CLK0b to $V_{DD}/2$ .                                      |
|     |           |                   | Output enable—Bank A (Outputs Q0 to Q2).  |
|     |           |                   | When OE = high, the Bank A outputs are enabled.   |
| 12  | OEA       | ı                 | When OE = low, Q is held low, and Qb is held high for differential formats.                                       |
|     |           |                   | For LVCMOS, both Q and Qb are held low when OE is set low.  |
|     |           |                   | OEA contains an internal pull-up resistor.  |
|     |           |                   | Output enable—Bank B (Outputs Q3 to Q5)   |
|     |           |                   | When OE = high, the Bank B outputs are enabled.   |
| 13  | OEB       | ı                 | When OE = low, Q is held low, and Qb is held high for differential formats.                                       |
|     |           |                   | For LVCMOS, both Q and Qb are held low when OE is set low.  |
|     |           |                   | OEB contains an internal pull-up resistor.  |
| 14  | CLK1      | I                 | Input clock 1   |
| 15  | CLK1b     |                   | Input clock 1 (complement)  |
| 10  | OLIVID    | '                 | When the CLK1 is driven by a single-end input, connect CLK1b to V <sub>DD</sub> /2.                               |
|     |           |                   | The LOS1 status pin indicates whether a clock is present at the CLK1 input:                                       |
| 16  | LOS1      | 0                 | CLK1 input clock present LOS1 = 0   |
|     |           |                   | CLK1 input clock not present LOS1 = 1   |
| 17  | VREF      | 0                 | Reference voltage output.   |
| 18  | VDDOA     | P                 | Output voltage supply—Bank A (Outputs: Q0 to Q2)  |
| 10  | VBBOX     |                   | Bypass with 1.0 μF capacitor and place as close to the VDDOA pin as possible.                                     |
| 19  | VDDOB     | P                 | Output voltage supply—Bank B (Outputs: Q3 to Q5)  |
|     |           |                   | Bypass with 1.0 µF capacitor and place as close to the VDDOB pin as possible.                                     |
| 20  | Q5b       | 0                 | Output clock 5 (complement)   |
| 21  | Q5        | 0                 | Output clock 5  |
|     |           |                   | Output signal format control pin for Bank B.  |
| 22  | SFOUTB[0] | SFOUTB[0] I       | Three-level input control. Internally biased at $V_{DD}/2$ . Can be left floating or tied to ground or $V_{DD}$ . |
|     |           |                   | . 55  |

| Pin     | Name      | Type <sup>1</sup> | Description   |
|---------|-----------|-------------------|---|
|         |           |                   | Output signal format control pin for Bank B.  |
| 23      | SFOUTB[1] | I                 | Three-level input control. Internally biased at $V_{DD}/2$ . Can be left floating or tied to ground or $V_{DD}$ . |
|         |           |                   | Output divider configuration bit for Bank B.  |
| 24      | DIVB      | I                 | Three-level input control. Internally biased at $V_{DD}/2$ . Can be left floating or tied to ground or $V_{DD}$ . |
| 25      | Q4b       | 0                 | Output clock 4 (complement)   |
| 26      | Q4        | 0                 | Output clock 4  |
| 27      | Q3b       | 0                 | Output clock 3 (complement)   |
| 28      | Q3        | 0                 | Output clock 3  |
| 29      | Q2b       | 0                 | Output clock 2 (complement)   |
| 30      | Q2        | 0                 | Output clock 2  |
| 31      | Q1b       | 0                 | Output clock 1 (complement)   |
| 32      | Q1        | 0                 | Output clock 1  |
| GND Pad | GND       | GND               | Power supply ground and thermal relief.   |

## 5.2 Si53302 Pin Descriptions

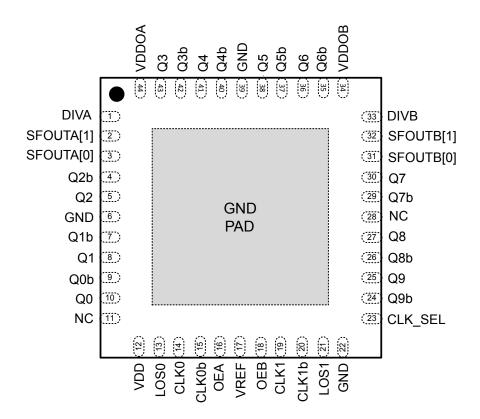


Table 5.2. Si53302 44-QFN Pin Descriptions

| Pin# | Name      | Type <sup>1</sup> | Description   |
|------|-----------|-------------------|---|
|      |           |                   | Output divider control pin for Bank A.  |
| 1    | DIVA      | I                 | Three-level input control. Internally biased at $V_{DD}/2$ . Can be left floating or tied to ground or $V_{DD}$ . |
|      |           |                   | Output signal format control pin for Bank A.  |
| 2    | SFOUTA[1] | I                 | Three-level input control. Internally biased at $V_{DD}/2$ . Can be left floating or tied to ground or $V_{DD}$ . |
|      |           |                   | Output signal format control pin for Bank A.  |
| 3    | SFOUTA[0] | I                 | Three-level input control. Internally biased at $V_{DD}/2$ . Can be left floating or tied to ground or $V_{DD}$ . |
| 4    | Q2b       | 0                 | Output clock 2 (complement).  |
| 5    | Q2        | 0                 | Output clock 2.   |
| 6    | GND       | GND               | Ground.   |
| 7    | Q1b       | 0                 | Output clock 1 (complement).  |
| 8    | Q1        | 0                 | Output clock 1.   |
| 9    | Q0b       | 0                 | Output clock 0 (complement).  |
| 10   | Q0        | 0                 | Output clock 0.   |
| 11   | NC        |                   | No connect. Do not connect this pin to anything.  |

| Pin# | Name     | Type <sup>1</sup> | Description   |
|------|----------|-------------------|---|
| 40   | 1/00     |                   | Core voltage supply.  |
| 12   | VDD      | Р                 | Bypass with a 1.0 µF capacitor placed as close to the pin as possible.              |
|      |          |                   | The LOS0 status pin indicates whether a clock is present at the CLK0 input:         |
| 13   | LOS0     | 0                 | CLK0 input clock present LOS0 = 0   |
|      |          |                   | CLK0 input clock not present LOS0 = 1   |
| 14   | CLK0     | I                 | Input clock 0.  |
| 45   | 01.1(01  |                   | Input clock 0 (complement).   |
| 15   | CLK0b    | Į Į               | When the CLK0 is driven by a single-end LVCMOS input, connect CLK0b to $V_{DD}/2$ . |
|      |          |                   | Output enable—Bank A.   |
|      |          |                   | When OEA = high, the Bank A outputs are enabled.                                    |
| 16   | OEA      | I                 | When OEA = low, Q is held low and Qb is held high for differential formats.         |
|      |          |                   | For LVCMOS, both Q and Qb are held low when OEA is set low.                         |
|      |          |                   | OEA contains an internal pull-up resistor.  |
| ,_   |          |                   | Reference voltage output.   |
| 17   | VREF     | 0                 | See section 2.3 Voltage Reference (V <sub>REF</sub> ) for details.                  |
|      |          |                   | Output enable—Bank B.   |
|      |          |                   | When OEB = high, the Bank B outputs are enabled.                                    |
| 18   | OEB      | I                 | When OEB = low, Q is held low and Qb is held high for differential formats.         |
|      |          |                   | For LVCMOS, both Q and Qb are held low when OEB is set low.                         |
|      |          |                   | OEB contains an internal pull-up resistor.  |
| 19   | CLK1     | I                 | Input clock 1.  |
|      | 01144    |                   | Input clock 1 (complement).   |
| 20   | CLK1b    | I                 | When the CLK1 is driven by a single-end LVCMOS input, connect CLK1b to $V_{DD}/2$ . |
|      |          |                   | The LOS1 status pin indicates whether a clock is present at the CLK1 input:         |
| 21   | LOS1     | О                 | CLK1 input clock present LOS1 = 0   |
|      |          |                   | CLK1 input clock not present LOS1 = 1   |
| 22   | GND      | GND               | Ground.   |
|      |          |                   | MUX input select pin (LVCMOS).  |
| 00   | 0114 051 |                   | When CLK_SEL is high, CLK1 is selected.   |
| 23   | CLK_SEL  | I                 | When CLK_SEL is low, CLK0 is selected.  |
|      |          |                   | CLK_SEL contains an internal pull-down resistor.                                    |
| 24   | Q9b      | 0                 | Output clock 9 (complement).  |
| 25   | Q9       | 0                 | Output clock 9.   |
| 26   | Q8b      | 0                 | Output clock 8 (complement).  |
| 27   | Q8       | 0                 | Output clock 8.   |
| 28   | NC       |                   | No connect.   |

| Pin#    | Name      | Type <sup>1</sup> | Description   |
|---------|-----------|-------------------|---|
| 29      | Q7b       | 0                 | Output clock 7 (complement).  |
| 30      | Q7        | 0                 | Output clock 7.   |
|         |           |                   | Output signal format control pin for Bank B.  |
| 31      | SFOUTB[0] | I                 | Three-level input control. Internally biased at $V_{DD}/2$ . Can be left floating or tied to ground or $V_{DD}$ . |
|         |           |                   | Output signal format control pin for Bank B.  |
| 32      | SFOUTB[1] | I                 | Three-level input control. Internally biased at $V_{DD}/2$ . Can be left floating or tied to ground or $V_{DD}$ . |
|         |           |                   | Output divider configuration bit for Bank B.  |
| 33      | DIVB      | I                 | Three-level input control. Internally biased at $V_{DD}/2$ . Can be left floating or tied to ground or $V_{DD}$ . |
| 0.4     | \/DDOD    | Р                 | Output Clock Voltage Supply—Bank B (Outputs: Q5 to Q9).   |
| 34      | VDDOB     |                   | Bypass with a 1.0 μF capacitor placed as close to the pin as possible.  |
| 35      | Q6b       | 0                 | Output clock 6 (complement).  |
| 36      | Q6        | 0                 | Output clock 6.   |
| 37      | Q5b       | 0                 | Output clock 5 (complement).  |
| 38      | Q5        | 0                 | Output clock 5.   |
| 39      | GND       | GND               | Ground.   |
| 40      | Q4b       | 0                 | Output clock 4 (complement).  |
| 41      | Q4        | 0                 | Output clock 4.   |
| 42      | Q3b       | 0                 | Output clock 3 (complement).  |
| 43      | Q3        | 0                 | Output clock 3.   |
| 44      | VDDOA     | D                 | Output Voltage Supply—Bank A (Outputs: Q0 to Q4).   |
| 44      | VDDOA     | Р                 | Bypass with a 1.0 μF capacitor placed as close to the pin as possible.  |
| CND Dod | CND       | CND               | Ground Pad.   |
| GND Pad | GND       | GND               | Power supply ground and thermal relief.   |

## 5.3 Si53303 Pin Descriptions

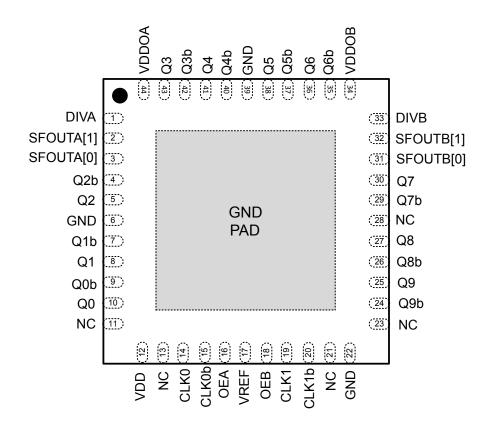


Table 5.3. Si53303 44-QFN Pin Descriptions

| Pin# | Name        | Type <sup>1</sup> | Description   |
|------|-------------|-------------------|---|
|      |             |                   | Output divider control pin for Bank A   |
| 1    | DIVA        | I                 | Three-level input control. Internally biased at VDD/2. Can be left floating or tied to ground or $V_{\rm DD}$ . |
|      |             |                   | Output signal format control pin for Bank A   |
| 2    | SFOUTA[1]   | I                 | Three-level input control. Internally biased at VDD/2. Can be left floating or tied to ground or $V_{DD}$ .     |
|      |             |                   | Output signal format control pin for Bank A   |
| 3    | 3 SFOUTA[0] | I                 | Three-level input control. Internally biased at VDD/2. Can be left floating or tied to ground or $V_{\rm DD}$ . |
| 4    | Q2b         | 0                 | Output clock 2 (complement)   |
| 5    | Q2          | 0                 | Output clock 2  |
| 6    | GND         | GND               | Ground  |
| 7    | Q1b         | 0                 | Output clock 1 (complement)   |
| 8    | Q1          | 0                 | Output clock 1  |
| 9    | Q0b         | 0                 | Output clock 0 (complement)   |
| 10   | Q0          | 0                 | Output clock 0  |
| 11   | NC          |                   | No connect. Do not connect this pin to anything.  |

| Pin# | Name      | Type <sup>1</sup> | Description   |
|------|-----------|-------------------|---|
| 40   | 1/00      |                   | Core voltage supply   |
| 12   | VDD       | Р                 | Bypass with 1.0 μF capacitor placed as close to the VDD pin as possible   |
| 13   | NC        |                   | No connect  |
| 14   | CLK0      | I                 | Input clock 0   |
|      | 011/01    |                   | Input clock 0 (complement)  |
| 15   | CLK0b     | 1                 | When the CLK0 is driven by a single-end LVCMOS input, connect CLK0b to $V_{DD}/2$ .                               |
|      |           |                   | Output enable—Bank A  |
|      |           |                   | When OE = high, the Bank A outputs are enabled  |
| 16   | OEA       | ı                 | When OE = low, Q is held low and Qb is held high for differential formats   |
|      |           |                   | For LVCMOS, both Q and Qb are held low when OE is set low   |
|      |           |                   | OEA contains an internal pull-up resistor   |
|      |           |                   | Reference voltage output.   |
| 17   | VREF      | 0                 | See section 2.3 Voltage Reference (V <sub>REF</sub> ) for details.  |
|      |           |                   | Output enable—Bank B  |
|      |           |                   | When OE = high, the Bank B outputs are enabled  |
| 18   | OEB       | ı                 | When OE = low, Q is held low and Qb is held high for differential formats   |
|      |           |                   | For LVCMOS, both Q and Qb are held low when OE is set low   |
|      |           |                   | OEB contains an internal pull-up resistor.  |
| 19   | CLK1      | I                 | Input clock 1   |
|      |           |                   | Input clock 1 (complement)  |
| 20   | CLK1b     | 1                 | When the CLK1 is driven by a single-end LVCMOS input, connect CLK1b to $V_{DD}/2$ .                               |
| 21   | NC        |                   | No connect  |
| 22   | GND       | GND               | Ground  |
| 23   | NC        |                   | No connect  |
| 24   | Q9b       | 0                 | Output clock 9 (complement)   |
| 25   | Q9        | 0                 | Output clock 9  |
| 26   | Q8b       | 0                 | Output clock 8 (complement)   |
| 27   | Q8        | 0                 | Output clock 8  |
| 28   | NC        |                   | No connect  |
| 29   | Q7b       | 0                 | Output clock 7 (complement)   |
| 30   | Q7        | 0                 | Output clock 7  |
|      |           |                   | Output signal format control pin for Bank B   |
| 31   | SFOUTB[0] | I                 | Three-level input control. Internally biased at $V_{DD}/2$ . Can be left floating or tied to ground or $V_{DD}$ . |
|      |           |                   | Output signal format control pin for Bank B   |
| 32   | SFOUTB[1] | I                 | Three-level input control. Internally biased at $V_{DD}/2$ . Can be left floating or tied to ground or $V_{DD}$ . |

| Pin #    | Name  | Type <sup>1</sup> | Description   |
|----------|-------|-------------------|---|
|          |       |                   | Output divider configuration bit for Bank B   |
| 33       | DIVB  | I                 | Three-level input control. Internally biased at $V_{DD}/2$ . Can be left floating or tied to ground or $V_{DD}$ . |
| 34       | VDDOB | Р                 | Output Clock Voltage Supply—Bank B (Outputs: Q5 to Q9)  |
| 34       | ADDOR | P P               | Bypass with 1.0 μF capacitor and place close to the VDDOB pin as possible.  |
| 35       | Q6b   | 0                 | Output clock 6 (complement)   |
| 36       | Q6    | 0                 | Output clock 6  |
| 37       | Q5b   | 0                 | Output clock 5 (complement)   |
| 38       | Q5    | 0                 | Output clock 5.   |
| 39       | GND   | GND               | Ground.   |
| 40       | Q4b   | 0                 | Output clock 4 (complement)   |
| 41       | Q4    | 0                 | Output clock 4.   |
| 42       | Q3b   | 0                 | Output clock 3 (complement)   |
| 43       | Q3    | 0                 | Output clock 3  |
| 4.4      | VDDOA |                   | Output Voltage Supply—Bank A (Outputs: Q0 to Q4)  |
| 44       | VDDOA | Р                 | Bypass with 1.0 μF capacitor and place close to the VDDOA pin as possible.  |
| CND Do d | CNID  | GND GND           | Ground Pad  |
| GND Pad  | GND   |                   | Power supply ground and thermal relief.   |

## 5.4 Si53304 Pin Descriptions

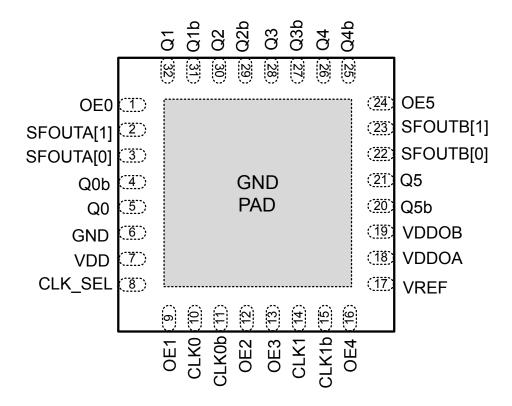


Table 5.4. Si53304 32-QFN Pin Descriptions

| Pin | Name      | Type <sup>1</sup> | Description   |
|-----|-----------|-------------------|---|
|     |           |                   | Output enable—Output 0  |
|     |           |                   | When OE = high, Q0 is enabled.  |
| 1   | OE0       | I                 | When OE = low, Q is held low and Qb is held high for differential formats.  |
|     |           |                   | For LVCMOS, both Q and Qb are held low when OE is set low.  |
|     |           |                   | This pin contains an internal pull-up resistor.   |
|     |           |                   | Output signal format control pin for Bank A   |
| 2   | SFOUTA[1] | I                 | Three level input control. Internally biased at $V_{DD}/2$ . Can be left floating or tied to ground or $V_{DD}$ . |
|     |           |                   | Output signal format control pin for Bank A   |
| 3   | SFOUTA[0] | I                 | Three level input control. Internally biased at $V_{DD}/2$ . Can be left floating or tied to ground or $V_{DD}$ . |
| 4   | Q0b       | 0                 | Output clock 0 (complement)   |
| 5   | Q0        | 0                 | Output clock 0  |
| 6   | GND       | GND               | Ground  |
| 7   | VDD       | Р                 | Core voltage supply   |
| /   | טטי       | ۲                 | Bypass with 1.0 $\mu F$ capacitor and place as close to the $V_{DD}$ pin as possible.                             |

| Pin | Name    | Type <sup>1</sup> | Description   |
|-----|---------|-------------------|---|
|     |         |                   | Mux input select pin (LVCMOS)   |
|     | CLK SEL |                   | When CLK_SEL is high, CLK1 is selected.   |
| 8   | CLK_SEL | I                 | When CLK_SEL is low, CLK0 is selected.  |
|     |         |                   | CLK_SEL contains an internal pull-down resistor.  |
|     |         |                   | Output enable—Output 1  |
|     |         |                   | When OE = high, Q1 is enabled.  |
| 9   | OE1     | I                 | When OE = low, Q is held low and Qb is held high for differential formats.                |
|     |         |                   | For LVCMOS, both Q and Qb are held low when OE is set low.                                |
|     |         |                   | This pin contains an internal pull-up resistor.   |
| 10  | CLK0    | I                 | Input clock 0   |
| 11  | CLK0b   | ı                 | Input clock 0 (complement)  |
| 11  | CLNOD   | <b>!</b>          | When the CLK0 is driven by a single-end input, connect CLK0b to V <sub>DD</sub> /2.       |
|     |         |                   | Output enable—Output 2  |
|     |         |                   | When OE = high, Q2 is enabled.  |
| 12  | OE2     | I                 | When OE = low, Q is held low and Qb is held high for differential formats.                |
|     |         |                   | For LVCMOS, both Q and Qb are held low when OE is set low.                                |
|     |         |                   | OE2 contains an internal pull-up resistor.  |
|     |         |                   | Output enable—Output 3  |
|     |         |                   | When OE = high, Q3 is enabled.  |
| 13  | OE3     | I                 | When OE = low, Q is held low and Qb is held high for differential formats.                |
|     |         |                   | For LVCMOS, both Q and Qb are held low when OE is set low.                                |
|     |         |                   | OE3 contains an internal pull-up resistor.  |
| 14  | CLK1    | I                 | Input clock 1   |
| 15  | CLK1b   | ı                 | Input clock 1 (complement)  |
| 10  | OLIVID  | , I               | When the CLK1 is driven by a single-end input, connect CLK1b to V <sub>DD</sub> /2.       |
|     |         |                   | Output enable—Output 4  |
|     |         |                   | When OE = high, Q4 is enabled.  |
| 16  | OE4     | I                 | When OE = low, Q is held low and Qb is held high for differential formats.                |
|     |         |                   | For LVCMOS, both Q and Qb are held low when OE is set low.                                |
|     |         |                   | This pin contains an internal pull-up resistor.   |
| 17  | VREF    | 0                 | See 2.3 Voltage Reference (V <sub>REF</sub> ) for details.                                |
| 10  | \/DDC^  | D                 | Output voltage supply—Bank A (Outputs: Q0 to Q2)  |
| 18  | VDDOA   | Р                 | Bypass with 1.0 μF capacitor and place as close to the V <sub>DDOA</sub> pin as possible. |
| 40  | VDDCD   | Б                 | Output voltage supply—Bank B (Outputs: Q3 to Q5)  |
| 19  | VDDOB   | Р                 | Bypass with 1.0 μF capacitor and place as close to the V <sub>DDOB</sub> pin as possible. |
| 20  | Q5b     | 0                 | Output clock 5 (complement)   |

| Pin      | Name      | Type <sup>1</sup> | Description   |
|----------|-----------|-------------------|---|
| 21       | Q5        | 0                 | Output clock 5  |
|          |           |                   | Output signal format control pin for Bank B   |
| 22       | SFOUTB[0] | I                 | Three level input control. Internally biased at $V_{DD}/2$ . Can be left floating or tied to ground or $V_{DD}$ . |
|          |           |                   | Output signal format control pin for Bank B   |
| 23       | SFOUTB[1] | I                 | Three level input control. Internally biased at $V_{DD}/2$ . Can be left floating or tied to ground or $V_{DD}$ . |
|          |           |                   | Output enable—Output 5  |
|          |           |                   | When OE = high, Q5 is enabled.  |
| 24       | OE5       | I                 | When OE = low, Q is held low and Qb is held high for differential formats.  |
|          |           |                   | For LVCMOS, both Q and Qb are held low when OE is set low.  |
|          |           |                   | This pin contains an internal pull-up resistor.   |
| 25       | Q4b       | 0                 | Output clock 4 (complement)   |
| 26       | Q4        | 0                 | Output clock 4  |
| 27       | Q3b       | 0                 | Output clock 3 (complement)   |
| 28       | Q3        | 0                 | Output clock 3  |
| 29       | Q2b       | 0                 | Output clock 2 (complement)   |
| 30       | Q2        | 0                 | Output clock 2  |
| 31       | Q1b       | 0                 | Output clock 1 (complement)   |
| 32       | Q1        | 0                 | Output clock 1  |
| GND Pad  | CND       | CND               | Ground Pad  |
| GIND Pau | GND       | ND GND            | Power supply ground and thermal relief.   |
| Noto     |           |                   |   |

<sup>1.</sup> Pin types are: I = input, O = output, P = power, GND = ground.

## 5.5 Si53305 Pin Descriptions

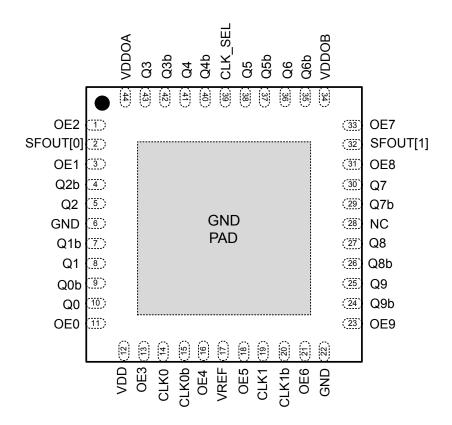


Table 5.5. Si53305 44-QFN Pin Descriptions

| Pin# | Name     | Type <sup>1</sup> | Description   |
|------|----------|-------------------|---|
|      |          |                   | Output enable—Output 2  |
|      |          |                   | When OE = high, Q2 is enabled.  |
| 1    | OE2      | I                 | When OE = low, Q is held low, and Qb is held high for differential formats.                                       |
|      |          |                   | For LVCMOS, both Q and Qb are held low when OE is set low.  |
|      |          |                   | OE2 contains an internal pull-up resistor.  |
|      |          |                   | Output signal format control pin [0]  |
| 2    | SFOUT[0] | 1                 | Three-level input control. Internally biased at $V_{DD}/2$ . Can be left floating or tied to ground or $V_{DD}$ . |
|      |          |                   | Output enable—Output 1  |
|      |          |                   | When OE = high, Q1 is enabled.  |
| 3    | OE1      | I                 | When OE = low, Q is held low, and Qb is held high for differential formats.                                       |
|      |          |                   | For LVCMOS, both Q and Qb are held low when OE is set low.  |
|      |          |                   | OE1 contains an internal pull-up resistor.  |
| 4    | Q2b      | 0                 | Output clock 2 (complement)   |
| 5    | Q2       | 0                 | Output clock 2  |
| 6    | GND      | GND               | Ground  |
| 7    | Q1b      | 0                 | Output clock 1 (complement)   |

| Pin # | Name   | Type <sup>1</sup> | Description   |  |  |  |
|-------|--------|-------------------|---|--|--|--|
| 8     | Q1     | 0                 | Output clock 1  |  |  |  |
| 9     | Q0b    | 0                 | Output clock 0 (complement)   |  |  |  |
| 10    | Q0     | 0                 | Output clock 0  |  |  |  |
|       |        |                   | Output enable—Output 0  |  |  |  |
|       |        |                   | When OE = high, Q0 is enabled.  |  |  |  |
| 11    | OE0    | I                 | When OE = low, Q is held low, and Qb is held high for differential formats.       |  |  |  |
|       |        |                   | For LVCMOS, both Q and Qb are held low when OE is set low.                        |  |  |  |
|       |        |                   | OE0 contains an internal pull-up resistor.  |  |  |  |
| 12    | VDD    | Р                 | Core voltage supply   |  |  |  |
| 12    | VUU    | P                 | Bypass with 1.0 µF capacitor and place close to the VDD pin as possible           |  |  |  |
|       |        |                   | Output Enable 3   |  |  |  |
|       |        |                   | When OE = high, Q3 is enabled.  |  |  |  |
| 13    | OE3    | ı                 | When OE = low, Q is held low, and Qb is held high for differential formats.       |  |  |  |
|       |        |                   | For LVCMOS, both Q and Qb are held low when OE is set low.                        |  |  |  |
|       |        |                   | OE3 contains an internal pull-up resistor.  |  |  |  |
| 14    | CLK0   | I                 | Input clock 0   |  |  |  |
| 15    | CLK0b  | ı                 | Input clock 0 (complement)  |  |  |  |
| 15    | CLRUD  |                   | When CLK0 is driven by a single-ended input, connect CLK0b to V <sub>DD</sub> /2. |  |  |  |
|       |        |                   | Output Enable 4   |  |  |  |
|       |        |                   | When OE = high, Q4 is enabled.  |  |  |  |
| 16    | OE4    | I                 | When OE = low, Q is held low, and Qb is held high for differential formats.       |  |  |  |
|       |        |                   | For LVCMOS, both Q and Qb are held low when OE is set low.                        |  |  |  |
|       |        |                   | OE4 contains an internal pull-up resistor.  |  |  |  |
| 47    | \/DEE  |                   | Reference voltage output.   |  |  |  |
| 17    | VREF   | 0                 | See 2.3 Voltage Reference (V <sub>REF</sub> ) for details.                        |  |  |  |
|       |        |                   | Output Enable 5   |  |  |  |
|       |        |                   | When OE = high, Q5 is enabled.  |  |  |  |
| 18    | OE5    | ı                 | When OE = low, Q is held low, and Qb is held high for differential formats.       |  |  |  |
|       |        |                   | For LVCMOS, both Q and Qb are held low when OE is set low.                        |  |  |  |
|       |        |                   | OE5 contains an internal pull-up resistor.  |  |  |  |
| 19    | CLK1   | I                 | Input clock 1   |  |  |  |
| 20    | CLIZAL |                   | Input clock 1 (complement)  |  |  |  |
| 20    | CLK1b  |                   | When CLK1 is driven by a single-ended input, connect CLK1b to $V_{DD}/2$ .        |  |  |  |

| Pin# | Name     | Type <sup>1</sup> | Description   |  |  |
|------|----------|-------------------|---|--|--|
|      |          |                   | Output Enable 6   |  |  |
|      |          |                   | When OE = high, Q6 is enabled.  |  |  |
| 21   | OE6      | ı                 | When OE = low, Q is held low, and Qb is held high for differential formats.                                       |  |  |
|      |          |                   | For LVCMOS, both Q and Qb are held low when OE is set low.  |  |  |
|      |          |                   | OE6 contains an internal pull-up resistor.  |  |  |
| 22   | GND      | GND               | Ground  |  |  |
|      |          |                   | Output Enable 9   |  |  |
|      |          |                   | When OE = high, Q9 is enabled.  |  |  |
| 23   | OE9      | ı                 | When OE = low, Q is held low, and Qb is held high for differential formats.                                       |  |  |
|      |          |                   | For LVCMOS, both Q and Qb are held low when OE is set low.  |  |  |
|      |          |                   | OE9 contains an internal pull-up resistor.  |  |  |
| 24   | Q9b      | 0                 | Output clock 9 (complement)   |  |  |
| 25   | Q9       | 0                 | Output clock 9  |  |  |
| 26   | Q8b      | 0                 | Output clock 8 (complement)   |  |  |
| 27   | Q8       | 0                 | Output clock 8  |  |  |
| 28   | NC       |                   | No Connect  |  |  |
| 29   | Q7b      | 0                 | Output clock 7 (complement)   |  |  |
| 30   | Q7       | 0                 | Output clock 7  |  |  |
|      |          |                   | Output Enable 8   |  |  |
|      |          |                   | When OE = high, Q8 is enabled.  |  |  |
| 31   | OE8      | I                 | When OE = low, Q is held low, and Qb is held high for differential formats.                                       |  |  |
|      |          |                   | For LVCMOS, both Q and Qb are held low when OE is set low.  |  |  |
|      |          |                   | OE8 contains an internal pull-up resistor.  |  |  |
|      |          |                   | Output signal format control pin [1]  |  |  |
| 32   | SFOUT[1] | l                 | Three-level input control. Internally biased at $V_{DD}/2$ . Can be left floating or tied to ground or $V_{DD}$ . |  |  |
|      |          |                   | Output Enable 7   |  |  |
|      |          |                   | When OE = high, Q7 is enabled.  |  |  |
| 33   | OE7      | ı                 | When OE = low, Q is held low, and Qb is held high for differential formats.                                       |  |  |
|      |          |                   | For LVCMOS, both Q and Qb are held low when OE is set low.  |  |  |
|      |          |                   | OE7 contains an internal pull-up resistor.  |  |  |
| 24   | VDDOB    | Р                 | Output voltage supply—Bank B (Outputs Q5 through Q9)  |  |  |
| 34   | ADDOR    |                   | Bypass with 1.0 μF capacitor and place as close to VDDOB pin as possible.   |  |  |
| 35   | Q6b      | 0                 | Output clock 6 (complement)   |  |  |
| 36   | Q6       | 0                 | Output clock 6  |  |  |
| 37   | Q5b      | 0                 | Output clock 5 (complement)   |  |  |
| 38   | Q5       | 0                 | Output clock 5  |  |  |

| Pin#    | Name    | Type <sup>1</sup> | Description   |
|---------|---------|-------------------|---|
|         |         |                   | MUX input select pin (LVCMOS)   |
| 20      | CLK CEI |                   | When CLK_SEL is high, CLK1 is selected                                    |
| 39      | CLK_SEL | I                 | When CLK_SEL is low, CLK0 is selected                                     |
|         |         |                   | CLK_SEL contains an internal pull-down resistor                           |
| 40      | Q4b     | 0                 | Output clock 4 (complement)   |
| 41      | Q4      | 0                 | Output clock 4  |
| 42      | Q3b     | 0                 | Output clock 3 (complement)   |
| 43      | Q3      | 0                 | Output clock 3  |
| 44      | VDDOA   | Р                 | Output voltage supply—Bank A (Outputs Q0 to Q4)                           |
| 44      | VDDOA   |                   | Bypass with 1.0 μF capacitor and place as close to VDDOA pin as possible. |
| CND Dad | GND     | CND               | Ground Pad  |
| GND Pad | GND     | GND               | Power supply ground and thermal relief                                    |

# 5.6 Si53306 Pin Descriptions

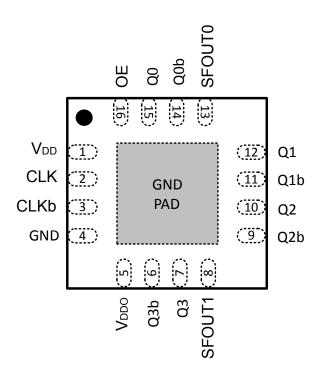


Table 5.6. Si53306 16-QFN Pin Descriptions

| Pin | Name   | Type <sup>1</sup> | Description   |  |
|-----|--------|-------------------|---|--|
| 1   | VDD    | Р                 | Core voltage supply.  |  |
| '   | VDD    |                   | Bypass with 1.0 μF capacitor and place as close to the VDD pin as possible.                           |  |
| 2   | CLK    | I                 | Input clock.  |  |
| 2   | CLKb   |                   | Input clock (complement).   |  |
| 3   | CLKD   | l I               | When the CLK is driven by a single-ended input, connect CLKb to VDD/2.                                |  |
| 4   | GND    | GND               | Ground.   |  |
| 5   | VDDO   | Р                 | Output voltage supply— All outputs (Q0 to Q3).  |  |
| 5   | VUUO   |                   | Bypass with 1.0 μF capacitor and place as close to the VDDO pin as possible.                          |  |
| 6   | Q3b    | 0                 | Output clock 3 (complement).  |  |
| 7   | Q3     | 0                 | Output clock 3.   |  |
|     |        |                   | Output signal format control pin 1.   |  |
| 8   | SFOUT1 | l                 | Three-level input control. Internally biased at VDD/2. Can be left floating or tied to ground or VDD. |  |
| 9   | Q2b    | 0                 | Output clock 2 (complement).  |  |
| 10  | Q2     | 0                 | Output clock 2.   |  |
| 11  | Q1b    | 0                 | Output clock 1 (complement).  |  |
| 12  | Q1     | 0                 | Output clock 1.   |  |

| Pin     | Name   | Type <sup>1</sup> | Description   |  |
|---------|--------|-------------------|---|--|
|         |        |                   | Output signal format control pin 0.   |  |
| 13      | SFOUT0 | I                 | Three-level input control. Internally biased at VDD/2. Can be left floating or tied to ground or VDD. |  |
| 14      | Q0b    | 0                 | Output clock 0 (complement).  |  |
| 15      | Q0     | 0                 | Output clock 0.   |  |
|         |        |                   | Output enable.  |  |
|         |        |                   | When OE = high, all outputs are enabled.  |  |
| 16      | OE     | I                 | When OE = low, Q is held low, and Qb is held high for differential formats.                           |  |
|         |        |                   | For LVCMOS, both Q and Qb are held low when OE is set low.  |  |
|         |        |                   | OE contains an internal pull-up resistor.   |  |
| GND Pad | GND    | GND               | Ground.   |  |

# 5.7 Si53307 Pin Descriptions

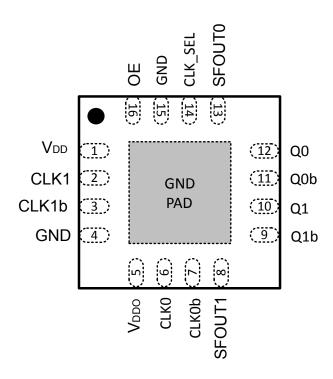


Table 5.7. Si53307 16-QFN Pin Descriptions

| Pin | Name   | Type <sup>1</sup> | Description   |  |
|-----|--------|-------------------|---|--|
| 1   | VDD    | Б                 | Core voltage supply.  |  |
| 1   | VDD    | Р                 | Bypass with 1.0 μF capacitor and place as close to the VDD pin as possible.                           |  |
| 2   | CLK1   | I                 | Input clock 1.  |  |
| 2   | CLICAL |                   | Input clock 1 (complement).   |  |
| 3   | CLK1b  | <b>'</b>          | When CLK1 is driven by a single-ended input, connect CLK1b to VDD/2.                                  |  |
| 4   | GND    | GND               | Ground.   |  |
| 5   | VDDO   | Р                 | Output clock supply voltage.  |  |
| 5   | VDDO   | Ρ                 | Bypass with 1.0 μF capacitor and place as close to the VDDO pin as possible.                          |  |
| 6   | CLK0   | I                 | Input clock 0.  |  |
| 7   | CLK0b  | 0b I              | Input clock 0 (complement).   |  |
| ,   | CLRUD  |                   | When CLK0 is driven by a single-ended input, connect CLK0b to VDD/2.                                  |  |
|     |        |                   | Output signal format control pin 1.   |  |
| 8   | SFOUT1 | I                 | Three-level input control. Internally biased at VDD/2. Can be left floating or tied to ground or VDD. |  |
| 9   | Q1b    | 0                 | Output clock 1 (complement).  |  |
| 10  | Q1     | 0                 | Output clock 1.   |  |
| 11  | Q0b    | 0                 | Output clock 0 (complement).  |  |
| 12  | Q0     | 0                 | Output clock 0.   |  |

| Pin     | Name    | Type <sup>1</sup> | Description   |  |  |
|---------|---------|-------------------|---|--|--|
|         |         | I                 | Output signal format control pin 0.   |  |  |
| 13      | SFOUT0  |                   | Three-level input control. Internally biased at VDD/2. Can be left floating or tied to ground or VDD. |  |  |
|         |         |                   | Mux input select pin:   |  |  |
| 14      | CIK SEI |                   | When CLK_SEL is high, CLK1 is selected.   |  |  |
| 14      | CLK_SEL | 1                 | When CLK_SEL is low, CLK0 is selected.  |  |  |
|         |         |                   | CLK_SEL contains an internal pull-down resistor.  |  |  |
| 15      | GND     | GND               | Ground.   |  |  |
|         |         |                   | Output enable.  |  |  |
|         |         |                   | When OE = high, all outputs are enabled.  |  |  |
| 16      | OE      | I                 | When OE = low, Q is held low, and Qb is held high for differential formats.                           |  |  |
|         |         |                   | For LVCMOS, both Q and Qb are held low when OE is set low.  |  |  |
|         |         |                   | OE contains an internal pull-up resistor.   |  |  |
| GND Pad | GND     | GND               | Ground.   |  |  |

<sup>1.</sup> Pin types are: I = input, O = output, P = power, GND = ground.

## 5.8 Si53308 Pin Descriptions

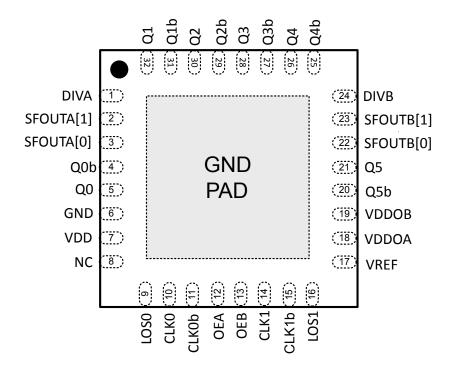


Table 5.8. Si53308 32-QFN Pin Descriptions

| Pin | Name      | Type <sup>1</sup> | Description  |
|-----|-----------|-------------------|--|
|     |           |                   | Output divider control pin for Bank A.   |
| 1   | DIVA      | l                 | Three-level input control. Internally biased at VDD/2. Can be left floating or tied to ground or VDD.            |
|     |           |                   | Output signal format control pin 1 for Bank A.   |
| 2   | SFOUTA[1] | I                 | Three-level input control. Internally biased at VDD/2. Can be left floating or tied to ground or VDD.            |
|     |           |                   | Output signal format control pin 0 for Bank A.   |
| 3   | SFOUTA[0] | I                 | Three-level input control. Internally biased at VDD/2. Can be left floating or tied to ground or VDD.            |
| 4   | Q0b       | 0                 | Output clock 0 (complement).   |
| 5   | Q0        | 0                 | Output clock 0.  |
| 6   | GND       | GND               | Ground.  |
| 7   | VDD       | Р                 | Core voltage supply.   |
| /   | VUU       | Ρ                 | Bypass with 1.0 µF capacitor and place close to the VDD pin as possible.   |
| 8   | NC        |                   | No connect.  |
| 9   | LOS0      | 0                 | The LOS0 status pin indicates whether a clock is present (LOS0 = 0) or not present (LOS0 = 1) at the CLK0 input. |
| 10  | CLK0      | I                 | Input clock 0.   |
| 11  | CLK0b     | ı                 | Input clock 0 (complement).  |
| 11  | CLNUD     | CLKUD I           | When CLK0 is driven by a single-ended input, connect CLK0b to VDD/2.   |

| Pin | Name      | Type <sup>1</sup> | Description  |  |
|-----|-----------|-------------------|--|--|
|     |           |                   | Output enable—Bank A.  |  |
|     |           |                   | When OE = high, the Bank A outputs are enabled.  |  |
| 12  | OEA       | I                 | When OE = low, Q is held low and Qb is held high for differential formats.                                       |  |
|     |           |                   | For LVCMOS, both Q and Qb are held low when OE is set low.   |  |
|     |           |                   | OEA contains an internal pull-up resistor.   |  |
|     |           |                   | Output enable—Bank B.  |  |
|     |           |                   | When OE = high, the Bank B outputs are enabled.  |  |
| 13  | OEB       | I                 | When OE = low, Q is held low and Qb is held high for differential formats.                                       |  |
|     |           |                   | For LVCMOS, both Q and Qb are held low when OE is set low.   |  |
|     |           |                   | OEB contains an internal pull-up resistor.   |  |
| 14  | CLK1      | I                 | Input clock 1.   |  |
| 15  | CLK1b     | ı                 | Input clock 1 (complement).  |  |
| 13  | OLIVID    | l l               | When CLK1 is driven by a single-ended input, connect CLK1b to VDD/2.   |  |
| 16  | LOS1      | 0                 | The LOS1 status pin indicates whether a clock is present (LOS1 = 0) or not present (LOS1 = 1) at the CLK1 input. |  |
| 17  | VREF      | 0                 | Reference voltage.   |  |
|     |           |                   | Output Clock Voltage Supply—Bank A (Outputs: Q0 to Q2).  |  |
| 18  | VDDOA     | Р                 | Bypass with 1.0 μF capacitor and place as close to the VDDOA pin as  |  |
|     |           |                   | possible.  |  |
|     |           |                   | Output Clock Voltage Supply—Bank B (Outputs: Q3 to Q5).  |  |
| 19  | VDDOB     | Р                 | Bypass with 1.0 μF capacitor and place as close to the VDDOB pin as  |  |
|     |           |                   | possible.  |  |
| 20  | Q5b       | 0                 | Output clock 5 (complement).   |  |
| 21  | Q5        | 0                 | Output clock 5.  |  |
|     |           |                   | Output signal format control pin 0 for Bank B.   |  |
| 22  | SFOUTB[0] | l                 | Three-level input control. Internally biased at VDD/2. Can be left floating or tied to ground or VDD.            |  |
|     |           |                   | Output signal format control pin 1 or Bank B.  |  |
| 23  | SFOUTB[1] | l                 | Three-level input control. Internally biased at VDD/2. Can be left floating or tied to ground or VDD.            |  |
|     |           |                   | Output divider control pin for Bank B.   |  |
| 24  | 24 DIVB   |                   | Three-level input control. Internally biased at VDD/2. Can be left floating or tied to ground or VDD.            |  |
| 25  | Q4b       | 0                 | Output clock 4 (complement).   |  |
| 26  | Q4        | 0                 | Output clock 4.  |  |
| 27  | Q3b       | 0                 | Output clock 3 (complement).   |  |
| 28  | Q3        | 0                 | Output clock 3.  |  |
| 29  | Q2b       | 0                 | Output clock 2 (complement).   |  |

| Pin     | Name | Type <sup>1</sup> | Description                             |
|---------|------|-------------------|---|
| 30      | Q2   | 0                 | Output clock 2.                         |
| 31      | Q1b  | 0                 | Output clock 1 (complement).            |
| 32      | Q1   | 0                 | Output clock 1.                         |
| CND Pod | GND  | GND               | Ground Pad.                             |
| GND Pad | GND  |                   | Power supply ground and thermal relief. |

# 6. Package Outlines

# 6.1 16-QFN Package Diagram

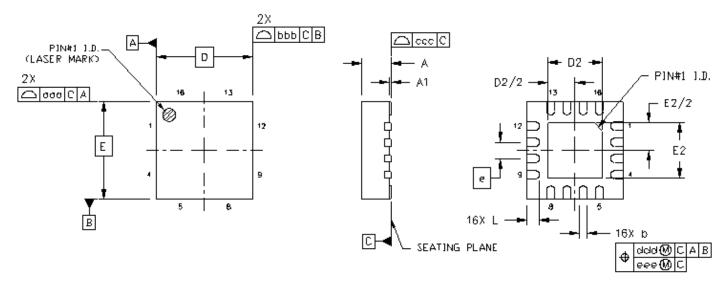


Figure 6.1. 3x3 mm 16-QFN Package Diagram Dimensions

Table 6.1. Package Diagram Dimensions

| Dimension | Min      | Nom      | Max  |  |  |
|-----------|----------|----------|------|--|--|
| А         | 0.80     | 0.85     | 0.90 |  |  |
| A1        | 0.00     | 0.02     | 0.05 |  |  |
| b         | 0.18     | 0.25     | 0.30 |  |  |
| D         |          | 3.00 BSC |      |  |  |
| D2        | 1.70     | 1.80     | 1.90 |  |  |
| е         | 0.50 BSC |          |      |  |  |
| E         |          | 3.00 BSC |      |  |  |
| E2        | 1.70     | 1.80     | 1.90 |  |  |
| L         | 0.30     | 0.40     | 0.50 |  |  |
| aaa       | _        | _        | 0.10 |  |  |
| bbb       | _        | _        | 0.10 |  |  |
| ccc       | _        | _        | 0.08 |  |  |
| ddd       | _        | _        | 0.10 |  |  |
| eee       | _        | _        | 0.05 |  |  |

### Notes:

- 1. All dimensions shown are in millimeters (mm) unless otherwise noted.
- 2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.

## 6.2 32-QFN Package Diagram

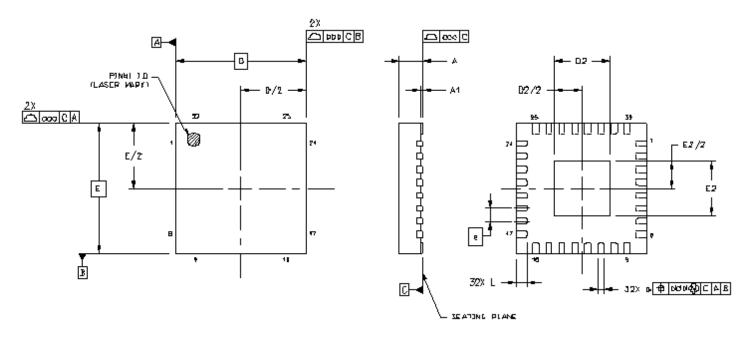


Figure 6.2. 5x5 mm 32-QFN Package Diagram Dimensions

Table 6.2. Package Diagram Dimensions

| Dimension | Min      | Nom      | Max  |  |
|-----------|----------|----------|------|--|
| A         | 0.80     | 0.85     | 1.00 |  |
| A1        | 0.00     | 0.02     | 0.05 |  |
| b         | 0.18     | 0.25     | 0.30 |  |
| С         | 0.20     | 0.25     | 0.30 |  |
| D         |          | 5.00 BSC |      |  |
| D2        | 2.00     | 2.15     | 2.30 |  |
| е         | 0.50 BSC |          |      |  |
| E         |          | 5.00 BSC |      |  |
| E2        | 2.00     | 2.15     | 2.30 |  |
| L         | 0.30     | 0.40     | 0.50 |  |
| aaa       | 0.10     |          |      |  |
| bbb       | 0.10     |          |      |  |
| ccc       | 0.08     |          |      |  |
| ddd       |          | 0.10     |      |  |

## Notes:

- 1. All dimensions shown are in millimeters (mm) unless otherwise noted.
- 2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.
- 3. This drawing conforms to the JEDEC Solid State Outline MO-220.

## 6.3 44-QFN Package Diagram

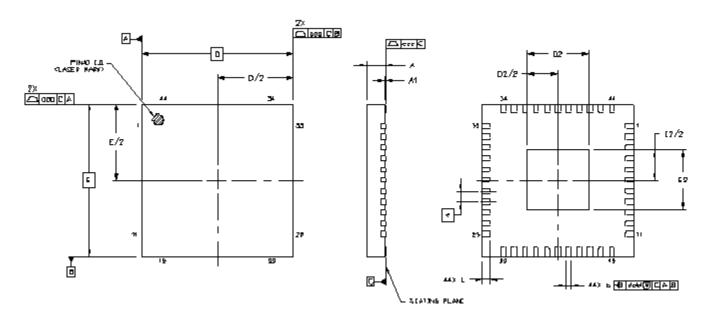


Figure 6.3. 7x7 mm 44-QFN Package Diagram Dimensions

Table 6.3. Package Diagram Dimensions

| Dimension | Min      | Nom  | Max  |
|-----------|----------|------|------|
| A         | 0.80     | 0.85 | 0.90 |
| A1        | 0.00     | 0.02 | 0.05 |
| b         | 0.18     | 0.25 | 0.30 |
| D         | 7.00 BSC |      |      |
| D2        | 2.65     | 2.80 | 2.95 |
| е         | 0.50 BSC |      |      |
| E         | 7.00 BSC |      |      |
| E2        | 2.65     | 2.80 | 2.95 |
| L         | 0.30     | 0.40 | 0.50 |
| aaa       | _        | _    | 0.10 |
| bbb       | _        | _    | 0.10 |
| ccc       | _        | _    | 0.08 |
| ddd       | _        | _    | 0.10 |

# Notes:

- 1. All dimensions shown are in millimeters (mm) unless otherwise noted.
- 2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.
- 3. This drawing conforms to the JEDEC Solid State Outline MO-220.
- 4. Recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

#### 7. Land Patterns

#### 7.1 16-QFN Land Pattern

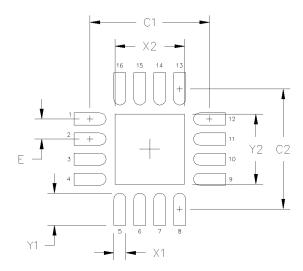


Figure 7.1. 3x3 mm 16-QFN Land Pattern

Table 7.1. PCB Land Pattern

| Dimension | mm   |
|-----------|------|
| C1        | 3.00 |
| C2        | 3.00 |
| E         | 0.50 |
| X1        | 0.30 |
| Y1        | 0.80 |
| X2        | 1.80 |
| Y2        | 1.80 |

### Notes:

# General

- 1. All dimensions shown are in millimeters (mm).
- 2. This Land Pattern Design is based on the IPC-7351 guidelines.
- 3. All dimensions shown are at Maximum Material Condition (MMC). Least Material Condition (LMC) is calculated based on a Fabrication Allowance of 0.05 mm.

## Solder Mask Design

1. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60mm minimum, all the way around the pad.

## Stencil Design

- 1. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.
- 2. The stencil thickness should be 0.125 mm (5 mils).
- 3. The ratio of stencil aperture to land pad size should be 1:1 for all perimeter pads.
- 4. A 2 x 2 array of 0.65 mm square openings on a 0.90 mm pitch should be used for the center ground pad.

## **Card Assembly**

- 1. A No-Clean, Type-3 solder paste is recommended.
- 2. The recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

#### 7.2 32-QFN Land Pattern

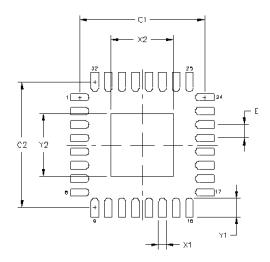


Figure 7.2. 5x5 mm 32-QFN Land Pattern

Table 7.2. PCB Land Pattern

| Dimension | Min  | Max  |
|-----------|------|------|
| C1        | 4.52 | 4.62 |
| C2        | 4.52 | 4.62 |
| E         | 0.50 | BSC  |
| X1        | 0.20 | 0.30 |
| X2        | 2.20 | 2.30 |
| Y1        | 0.59 | 0.69 |
| Y2        | 2.20 | 2.30 |

#### Notes:

#### General

- 1. All dimensions shown are in millimeters (mm) unless otherwise noted.
- 2. This Land Pattern Design is based on the IPC-7351 guidelines.

#### Solder Mask Design

1. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 µm minimum, all the way around the pad.

## Stencil Design

- 1. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.
- 2. The stencil thickness should be 0.125 mm (5 mils).
- 3. The ratio of stencil aperture to land pad size should be 1:1 for all perimeter pads.
- 4. A 2×2 array of 0.75 mm square openings on 1.15 mm pitch should be used for the center ground pad.

## **Card Assembly**

- 1. A No-Clean, Type-3 solder paste is recommended.
- 2. The recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

#### 7.3 44-QFN Land Pattern

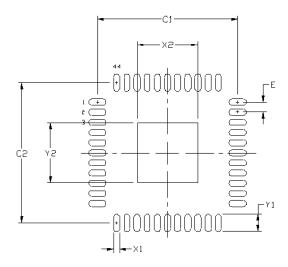


Figure 7.3. 7x7 mm 44-QFN Land Pattern

Table 7.3. PCB Land Pattern

| Dimension | Min  | Max  |
|-----------|------|------|
| C1        | 6.80 | 6.90 |
| C2        | 6.80 | 6.90 |
| E         | 0.50 | BSC  |
| X1        | 0.20 | 0.30 |
| X2        | 2.85 | 2.95 |
| Y1        | 0.75 | 0.85 |
| Y2        | 2.85 | 2.95 |

#### Notes:

#### General

- 1. All dimensions shown are in millimeters (mm) unless otherwise noted.
- 2. This Land Pattern Design is based on the IPC-7351 guidelines.

#### Solder Mask Design

1. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 µm minimum, all the way around the pad.

## Stencil Design

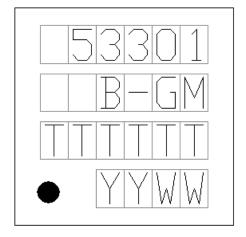
- 1. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.
- 2. The stencil thickness should be 0.125 mm (5 mils).
- 3. The ratio of stencil aperture to land pad size should be 1:1 for all perimeter pads.
- 4. A 2×2 array of 1.0 mm square openings on 1.45 mm pitch should be used for the center ground pad.

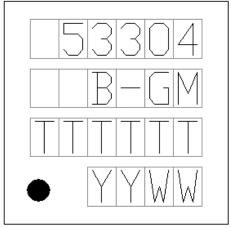
## **Card Assembly**

- 1. A No-Clean, Type-3 solder paste is recommended.
- 2. The recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

# 8. Top Markings

# 8.1 Si53301/04/08 Top Markings





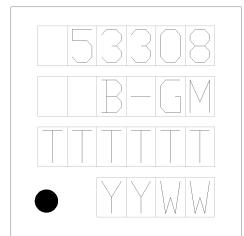


Figure 8.1. Si53301 Top Marking

Figure 8.2. Si53304 Top Marking

Figure 8.3. Si53308 Top Marking

Table 8.1. Si53301/04/08 32-QFN Top Marking Explanation

| Mark Method:    | Laser  |  |
|-----------------|--|--|
| Font Size:      | 2.0 Point (28 mils)<br>Center-Justified          |  |
| Line 1 Marking: | Device Part Number                               | 53301 for Si53301-B-GM   |
|                 |  | 53304 for Si53304-B-GM   |
|                 |  | 53308 for Si53308-B-GM   |
| Line 2 Marking: | Device Revision/Type                             | B-GM   |
| Line 3 Marking: | TTTTTT = Mfg Code                                | Manufacturing Code   |
| Line 4 Marking  | Circle = 0.5 mm Diameter<br>Lower-Left Justified | Pin 1 Identifier   |
|                 | YY = Year<br>WW = Work Week                      | Assigned by Assembly Supplier. Corresponds to the year and work week of the mold date. |

# 8.2 Si53302/03/05 Top Markings



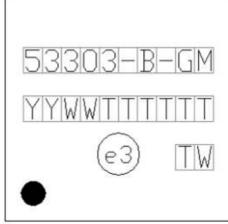




Figure 8.4. Si53302 Top Marking

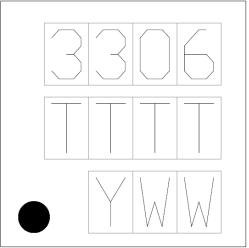
Figure 8.5. Si53303 Top Marking

Figure 8.6. Si53305 Top Marking

Table 8.2. Si53302/03/05 44-QFN Top Marking Explanation

| Mark Method:    | Laser                                      |   |
|-----------------|--|---|
| Font Size:      | 1.9 Point (26 mils)<br>Right-Justified     |   |
| Line 1 Marking: | Device Part Number                         | 53302 for Si53302-B-GM  |
|                 |  | 53303 for Si53303-B-GM  |
|                 |  | 53305 for Si53305-B-GM  |
| Line 2 Marking: | YY = Year                                  | Assigned by Assembly Supplier. Corresponds to the year and work week of |
|                 | WW=Work Week                               | the mold date.  |
|                 | TTTTTT = Mfg Code                          | Manufacturing Code from the Assembly Purchase Order form.               |
| Line 3 Marking: | Circle=1.3 mm Diameter<br>Center-Justified | "e3" Pb-Free Symbol   |
|                 | Country of Origin                          | TW  |
|                 | ISO Code Abbreviation                      |   |
| Line 4 Marking  | Circle = 0.75 mm Diameter Filled           | Pin 1 Identification  |

# 8.3 Si53306/07 Top Markings



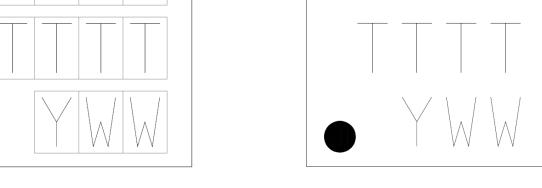


Figure 8.7. Si53306 Top Marking

Figure 8.8. Si53307 Top Marking

Table 8.3. Si53306/07 Top Marking Explanation

| Mark Method:    | Laser   |   |
|-----------------|---|---|
| Font Size:      | 0.635 mm (25 mils)<br>Right-Justified             |   |
| Line 1 Marking: | Device Part Number                                | 3306 for Si53306-B-GM   |
|                 | Device Part Number                                | 3307 for Si53307-B-GM   |
|                 | TTTT = Mfg Code                                   | Manufacturing Code from the Assembly Purchase Order form.                                     |
| Line 2 Marking: | YY = Year<br>WW=Work Week                         | Assigned by Assembly Supplier. Corresponds to the year and work week of the mold date.        |
| Line 3 Marking: | Circle=0.5 mm Diameter<br>(Bottom-Left Justified) | Pin 1 Identifier  |
|                 | YWW = Date Code                                   | Corresponds to the last digit of the current year (Y) and the workweek (WW) of the mold date. |

# 9. Revision History

**Revision 1.0** 

April, 2019

Initial release.









www.skyworksinc.com/CBPro



**Quality** www.skyworksinc.com/quality



**Support & Resources** www.skyworksinc.com/support

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